







**BQ21061** JAJSHW6A - SEPTEMBER 2019 - REVISED AUGUST 2023

# BQ21061 10nA の出荷モード、レギュレートされたシステム (PMID) 電圧を含 むパワー・パス、および LDO 搭載、I<sup>2</sup>C 制御型 1 セル 500mA リニア・バッテ リ充電器

## 1 特長

- 1.25mA~500mA の高速充電電流範囲に対応したリ ニア・バッテリ充電器
  - I<sup>2</sup>C を使用して精度 0.5% でプログラム可能なバッ テリ・レギュレーション電圧 (3.6V~4.6V の範囲で 10mV 刻み)
  - 終了電流を最小 0.5mA に設定可能
  - 入力耐圧 20V で、標準的な入力電圧動作範囲は 3.4V~5.5V
  - 熱充電プロファイルをプログラム可能、ホット、ウォ ーム、クール、コールドの各スレッショルドを設定可
- システム電源およびバッテリ充電用のパワー・パス管理
  - バッテリ電圧トラッキングと入力パススルーのオプシ ョンに加えて、I2Cを使用してプログラム可能なレギ ュレートされたシステム (PMID) 電圧 (4.4V~4.9V)
  - 動的なパワー・パス管理により、弱いアダプタからの 充電を最適化
  - 高度な I2C 制御により、ホストは必要に応じてバッ テリまたはアダプタを切り離し可能
- I<sup>2</sup>C によりロード・スイッチまたは最大 150mA の LDO 出力を設定可能
  - 0.6V~3.7V の範囲で 100mV 刻みでプログラム可
- 非常に低い Iddq によりバッテリ駆動時間を延長
  - 出荷モードのバッテリ la:10nA
  - システム駆動時 (PMID および VDD がオン) の Iq:400nA
- 押しボタン 1 つによる可変タイマ付きウェイクアップお よびリセット入力
  - システム電源サイクルおよび HW リセットをサポート
- 安全関連認証
  - TUV IEC 62368 認証
- 20 ピンの 2mm × 1.6mm CSP パッケージ
- ソリューション全体のサイズ:11mm<sup>2</sup>

# 2 アプリケーション

- ヘッドセット、イヤホン、補聴器
- スマートウォッチ、スマート・トラッカー
- ウェアラブル型フィットネスおよびアクティビティ・モニタ
- 血糖値モニタ

# 3 概要

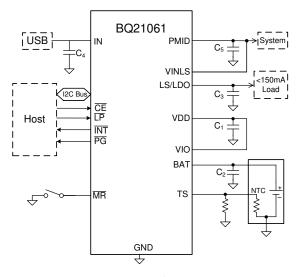
BQ21061 はウェアラブル、携帯型、および小型の医療機 器の最も一般的な機能(例:充電器、システム電力用のレ ギュレートされた出力電圧レール、LDO、押しボタン・コン トローラ) を統合した高集積バッテリ充電管理 IC です。

BQ21061 IC はパワー・パス付きリニア充電器を内蔵し、 レギュレートされた電圧をシステムに供給すると同時に、小 型バッテリを急速かつ正確に充電できます。レギュレートさ れたシステム電圧 (PMID) 出力は、システムを最適に動作 させるために、ダウンストリーム IC の推奨動作条件とシス テム負荷に基づき、I2Cを介して設定できます。

## 製品情報

| 部品番号    | パッケージ <sup>(1)</sup> | 本体サイズ (公称)      |
|---------|----------------------|-----------------|
| BQ21061 | DSBGA (20)           | 2.00mm × 1.60mm |

利用可能なすべてのパッケージについては、このデータシートの 末尾にある注文情報を参照してください。



概略回路図



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# **4 Revision History**

資料番号末尾の英字は改訂を表しています。その改訂履歴は英語版に準じています。

| C | hanges from Revision * (September 2019) to Revision A (August 2023)   | Page            |
|---|---|-----------------|
| • | ドキュメント全体にわたって表、図、相互参照の採番方法を更新   | 1               |
| • | 「特長」に「安全関連認証」を追加  | 1               |
| • | Added clarification to $\overline{LP}$ pin description  | 3               |
|   | Added clarification to LS/LDO pin description   |                 |
| • | Changed maximum I <sub>PMID</sub> in Recommended Operating Conditions   | <mark>5</mark>  |
| • | Changed t <sub>HW RESET WD</sub> test conditions and MAX value from 15s to 14s in Timing Requirements                 | 8               |
|   | Changed t <sub>RESET</sub> warn and t <sub>HW RESET</sub> parameters  |                 |
|   | Changed t <sub>HW RESET WARN</sub> to t <sub>RESET WARN</sub> and VIN presence to valid VIN presence in セクション 7.3.7.2 |                 |
|   | Added clarification to TS biasing operation   |                 |
| • | Changed from as well while the VIN input is valid to while the VIN input is valid in セクション 7.4.1                      | <mark>27</mark> |
| • | Changed description of IBAT_OCP_ILIM 2b10 setting to "Disable" to describe correct behavior                           |                 |
| • | Changed clarification to TS EN bit functionality  |                 |
| • | Changed 🗵 8-3   |                 |
|   |   |                 |

Product Folder Links: BQ21061



# **5 Pin Configuration and Functions**

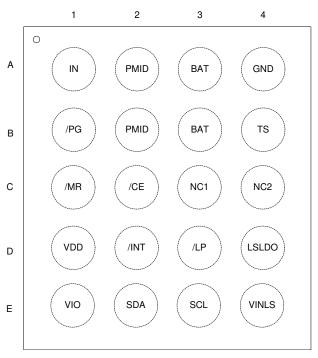


図 5-1. YFP Package 20-Pin DSBGA Top View

表 5-1. Pin Functions

|        | PIN    |       | DECORPTION  |  |
|--------|--------|-------|---|--|
| NAME   | NO.    | - I/O | DESCRIPTION   |  |
| IN     | A1     | I     | DC Input Power Supply. IN is connected to the external DC supply. Bypass IN to GND with at least 1-µF of capacitance using a ceramic capacitor.   |  |
| PMID   | A2, B2 | I/O   | Regulated System Output. Connect 22-µF capacitor from PMID to GND as close to the PMID and GND pins as possible. If operating in VIN Pass-Through Mode (PMID_REG = 111) a lower capacitor value may be used (at least 3-µF of ceramic capacitance with DC bias de-rating).  |  |
| GND    | A4     | PWR   | Ground connection. Connect to the ground plane of the circuit.  |  |
| VDD    | D1     | 0     | Digital supply LDO. Connect a 2.2-μF from this pin to ground.   |  |
| CE     | C2     | I     | Charge Enable. Drive $\overline{\text{CE}}$ low or leave disconnected to enable charging when VIN is valid. $\overline{\text{CE}}$ is pulled low internally with 900-kΩ resistor.   |  |
| SCL    | E3     | I/O   | I <sup>2</sup> C Interface Clock. Connect SCL to the logic rail through a 10-kΩ resistor.   |  |
| SDA    | E2     | 1     | l <sup>2</sup> C Interface Data. Connect SDA to the logic rail through a 10-kΩ resistor.  |  |
| LP     | D3     | I     | Low Power Mode Enable. Drive this pin low to set the device in low power mode when powered by the battery. This pin must be driven high to allow $I^2C$ communication when VIN is not present. $\overline{LP}$ is pulled low internally with $900\text{-k}\Omega$ resistor. This pin has no effect when VIN is present. |  |
| INT    | D2     | 0     | ĪNT is an open-drain output that signals fault interrupts. When a fault occurs, a 128-µs pulse is sent out as an interrupt for the host.  |  |
| MR     | C1     | I     | Manual Reset Input. $\overline{MR}$ is a general purpose input used to reset the device or to wake it up from Ship Mode. $\overline{MR}$ has in internal 125-k $\Omega$ pull-up resistor to BAT.  |  |
| LS/LDO | D4     | 0     | Load Switch or LDO output. Connect 2.2 $\mu$ F of ceramic capacitance to this pin to assure stability. Be sure to account for capacitance bias voltage derating when selecting the capacitor. If LDO is not used, short to VINLS  |  |
| VINLS  | E4     | I     | Input to the Load Switch / LDO output. Connect at least 1 µF of ceramic capacitance from this pin to ground.  |  |



# 表 5-1. Pin Functions (continued)

| P    | PIN I/O |     | DESCRIPTION  |
|------|---------|-----|--|
| NAME | NO.     | 1/0 | DESCRIPTION  |
| BAT  | A3, B3  | I/O | Battery Connection. Connect to the positive terminal of the battery. Bypass BAT to GND with at least 1 $\mu$ F of ceramic capacitance.   |
| TS   | B4      | I   | Battery Pack NTC Monitor. Connect TS to a 10-k $\Omega$ NTC thermistor in parallel to a 10-k $\Omega$ resistor. If TS function is not to be used connect a 5-k $\Omega$ resistor from TS to ground.          |
| PG   | B1      | 0   | Open-drain Power Good status indication output. The $\overline{PG}$ pin can also be configured as a general purpose open drain output or level shifter version of $\overline{MR}$ .                          |
| VIO  | E1      | I   | System IO supply. Connect to system IO supply to allow level shifting of input signals (SDA, SCL, LP and CE) to the device internal digital domain. Connect to VDD when external IO supply is not available. |
| NC1  | C3      | I   | No Connect. Connect to ground if possible for better thermal dissipation or leave floating. Do not connect to a any voltage source or signal to avoid higher quiescent current.                              |
| NC2  | C4      | I   | No Connect. Connect to ground if possible for better thermal dissipation. May be shorted to /LP for easier routing as long as Absolute Maximum Rating requirements are met                                   |



# **6 Specifications**

# **6.1 Absolute Maximum Ratings**

over operating free-air temperature range (unless otherwise noted)(1)

|                |                                      | MIN  | MAX  | UNIT |
|----------------|--------------------------------------|------|------|------|
| Voltage        | IN                                   | -0.3 | 20   | V    |
|                | TS,VDD, NC                           | -0.3 | 1.95 | V    |
|                | All other pins                       | -0.3 | 5.5  | V    |
|                | IN                                   | 0    | 800  | mA   |
| Current        | BAT, PMID                            | -0.5 | 1.5  | Α    |
|                | INT, PG                              | 0    | 10   | mA   |
| Junction tempe | Junction temperature, T <sub>J</sub> |      | 125  | °C   |
| Storage tempe  | erature, T <sub>stg</sub>            | -55  | 150  | °C   |

<sup>(1)</sup> Stresses beyond those listed under Absolute Maximum Rating may cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Condition. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

# 6.2 ESD Ratings

|                    |                         |  | VALUE | UNIT |
|--------------------|-------------------------|--|-------|------|
|                    | Cleatractatic discharge | Human body model (HBM), per ANSI/ESDA/<br>JEDEC JS-001, all pins <sup>(1)</sup>          | ±2000 | V    |
| V <sub>(ESD)</sub> | Electrostatic discharge | Charged device model (CDM), per JEDEC specification JESD22-C101, all pins <sup>(2)</sup> | ±500  | V    |

- (1) JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.
- (2) JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.

## **6.3 Recommended Operating Conditions**

over operating free-air temperature range (unless otherwise noted)

|                   |                                      | MIN  | NOM MAX             | UNIT |
|-------------------|--------------------------------------|------|---------------------|------|
| V <sub>BAT</sub>  | Battery voltage range                | 2.4  | 4.6                 | V    |
| V <sub>IN</sub>   | Input voltage range                  | 3.15 | 5.25 <sup>(1)</sup> | V    |
| V <sub>INLS</sub> | LDO input voltage range              | 2.2  | 5.25 <sup>(1)</sup> | V    |
| V <sub>IO</sub>   | IO supply voltage range              | 1.2  | 3.6                 | V    |
| I <sub>LDO</sub>  | LDO output current                   | 0    | 100                 | mA   |
| I <sub>PMID</sub> | PMID output current                  | 0    | 1.5                 | Α    |
| T <sub>A</sub>    | Operating free-air temperature range | -40  | 85                  | °C   |

<sup>(1)</sup> Based on minimum V<sub>OVP</sub> value. 5.5V under typical conditions

#### **6.4 Thermal Information**

|                       |  | BQ21061     |      |
|-----------------------|--|-------------|------|
|                       | THERMAL METRIC <sup>(1)</sup>              | YFP (DSBGA) | UNIT |
|                       |  | 20-PIN      |      |
| R <sub>0JA</sub>      | Junction-to-ambient thermal resistance (2) | 36.1        | °C/W |
| R <sub>0JA</sub>      | Junction-to-ambient thermal resistance     | 74.4        | °C/W |
| R <sub>0JC(top)</sub> | Junction-to-case (top) thermal resistance  | 0.5         | °C/W |
| R <sub>0JB</sub>      | Junction-to-board thermal resistance       | 17.6        | °C/W |
| $\Psi_{JT}$           | Junction-to-top characterization parameter | 0.3         | °C/W |



# 6.4 Thermal Information (continued)

|                      |  | BQ21061     |      |
|----------------------|--|-------------|------|
|                      | THERMAL METRIC <sup>(1)</sup>                | YFP (DSBGA) | UNIT |
|                      |  | 20-PIN      |      |
| $\Psi_{JB}$          | Junction-to-board characterization parameter | 17.7        | °C/W |
| $R_{\theta JC(bot)}$ | Junction-to-case (bottom) thermal resistance | N/A         | °C/W |

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report.

#### 6.5 Electrical Characteristics

 $V_{IN}$  = 5V,  $V_{BAT}$  = 3.6V.  $T_J$  = 25°C unless otherwise noted.

|                           | PARAMETER   | TEST CONDITIONS  | MIN | TYP   | MAX | UNIT |
|---------------------------|---|--|-----|---|-----|------|
| INPUT C                   | JRRENTS   |  |     |   |     |      |
|                           | Innut ourselv oursest                                 | PMID_MODE = 01, V <sub>IN</sub> = 5V, V <sub>BAT</sub> = 3.6V  |     |   | 500 | μA   |
| I <sub>IN</sub>           | Input supply current                                  | V <sub>IN</sub> = 5V, V <sub>BAT</sub> = 3.6V Charge Disabled  |     |   | 1.6 | mA   |
| I <sub>BAT_SHIP</sub>     | Battery Discharge Current in Ship Mode                | V <sub>IN</sub> = 0V , V <sub>BAT</sub> = 3.6V   |     | 10  |     | nA   |
|                           | Battery Quiescent Current in Low-power                | V <sub>IN</sub> = 0V , V <sub>BAT</sub> = 3.6V, LDO Disabled   |     | 0.46  | 0.9 | μA   |
| I <sub>BAT_LP</sub>       | Mode  | V <sub>IN</sub> = 0V , V <sub>BAT</sub> = 3.6V, LDO Enabled  |     | 1.7   | 1.9 | μA   |
| I <sub>BAT_ACTI</sub>     | Battery Quiescent Current in Active Mode              | V <sub>IN</sub> = 0V , V <sub>BAT</sub> = 3.6V, LDO Disabled   |     | 18  | 23  | μA   |
| VE                        | Battery Quiescent Current in Active Mode              | V <sub>IN</sub> = 0V , V <sub>BAT</sub> = 3.6V, LDO Enabled  |     | 21  | 25  | μA   |
| POWER I                   | PATH MANAGEMENT AND INPUT CURRE                       | ENT LIMIT  |     |   |     |      |
| V <sub>PMID_RE</sub><br>G | Default System (PMID) Regulation<br>Voltage           |  |     | 4.5   |     | V    |
| $V_{PMID\_RE}$            | System Degulation Valtage Assurably                   | V <sub>IN</sub> = 5V, V <sub>PMID_REG</sub> = 4.5V. I <sub>PMID</sub> = 100mA, T <sub>J</sub> = 25°C | -1  |   | 1   | %    |
| G_ACC                     | System Regulation Voltage Accuracy                    | V <sub>IN</sub> = 5V, V <sub>PMID_REG</sub> = 4.5V. I <sub>PMID</sub> = 0-<br>500mA                  | -3  |   | 3   | %    |
| R <sub>ON(IN-</sub>       | Input FET ON resistance                               | I <sub>ILIM</sub> = 500mA (ILIM = 110), V <sub>IN</sub> = 5V, I <sub>IN</sub> = 150mA                |     | 280   | 520 | mΩ   |
| V <sub>BSUP1</sub>        | Enter supplements mode threshold                      | V <sub>BAT</sub> > V <sub>BATUVLO</sub> , DPPM enabled or<br>Charge disabled                         |     | V <sub>PMID</sub> <<br>V <sub>BAT</sub> –<br>40mV |     | mV   |
| V <sub>BSUP2</sub>        | Exit supplements mode threshold                       | V <sub>BAT</sub> > V <sub>BATUVLO</sub> , DPPM enabled or<br>Charge disabled                         |     | V <sub>PMID</sub> <<br>V <sub>BAT</sub> –<br>20mV |     | mV   |
|                           |   | Programmable Range   | 50  |   | 600 | mA   |
|                           |   | I <sub>ILIM</sub> = 50mA   |     | 45  | 50  | mA   |
| I <sub>ILIM</sub>         | Input Current Limit                                   | I <sub>ILIM</sub> = 100mA  |     | 90  | 100 | mA   |
|                           |   | I <sub>ILIM</sub> = 150mA  |     | 135   | 150 | mA   |
|                           |   | I <sub>ILIM</sub> = 500mA  |     | 450   | 500 | mA   |
| V <sub>IN DPM</sub>       | Input DPM voltage threshold where current in reduced  | Programmable Range   | 4.2 |   | 4.9 | V    |
| _                         | Accuracy  |  | -3  |   | 3   | %    |
| BATTERY                   | CHARGER   |  |     |   | "   |      |
| $V_{DPPM}$                | PMID voltage threshold when charge current is reduced | V <sub>PMID</sub> - V <sub>BAT</sub>   |     | 200   |     | mV   |
| R <sub>ON(BAT-</sub>      | Battery Discharge FET On Resistance                   | V <sub>BAT</sub> = 4.35V, I <sub>BAT</sub> = 100mA   |     | 100   | 175 | mΩ   |
| \/                        | Charge Voltage  | Programmable charge voltage range  | 3.6 |   | 4.6 | V    |
| V <sub>BATREG</sub>       | Voltage Regulation Accuracy                           |  | 0.5 |   | 0.5 | %    |

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English Data Sheet: SLUSDU0

<sup>(2)</sup> Measured in BQ21061EVM board.



# **6.5 Electrical Characteristics (continued)**

 $V_{INI} = 5V$ ,  $V_{PAT} = 3.6V$ ,  $T_{II} = 25^{\circ}$ C unless otherwise noted.

|  | PARAMETER  | TEST CONDITIONS  | MIN                                   | TYP           | MAX                  | UNIT |
|--|--|--|---------------------------------------|---------------|----------------------|------|
| I <sub>CHARGE</sub>                      | Fast Charge Programmable Current Range                                       | V <sub>LOWV</sub> < V <sub>BAT</sub> < V <sub>BATREG</sub>   | 1.25                                  |               | 500                  | mA   |
|  | Fast Charge Current Accuracy   | I <sub>CHARGE</sub> > 5mA  | -5                                    |               | 5                    | %    |
| PRECHAR                                  | Precharge current  | Precharge current programmable range   | 1.25                                  |               | 77.5                 | mA   |
| GE                                       | Precharge Current Accuracy   | -40°C < T <sub>J</sub> < 85°C  | -10                                   |               | 10                   | %    |
| I <sub>TERM</sub>                        | Termination Charge Current   | Termination Current Programmable Range   | 1                                     |               | 31                   | %    |
|  | Accuracy   | I <sub>TERM</sub> = 10% I <sub>CHARGE</sub> , I <sub>CHARGE</sub> = 100mA                                    | <b>-</b> 5 <sup>(1)</sup>             |               | 5 <sup>(1)</sup>     | %    |
| $V_{LOWV}$                               | Programmable voltage threshold for pre-<br>charge to fast charge transitions | VBAT rising. Programmable Range  | 2.8                                   |               | 3                    | V    |
| V <sub>SHORT</sub>                       | Battery voltage threshold for short detection                                | VBAT falling, VIN = 5V   | 2.41                                  | 2.54          | 2.67                 | V    |
| I <sub>SHORT</sub>                       | Charge Current in Battery Short Condition                                    | V <sub>BAT</sub> < V <sub>SHORT</sub>  | I                                     | PRECHAR<br>GE |                      | mA   |
| $V_{RCH}$                                | Recharge Threshold voltage   | V <sub>BAT</sub> falling, V <sub>BATREG</sub> = 4.2V, V <sub>RCH</sub> = 140mV setting                       |                                       | 140           |                      | mV   |
| ▼ RCH                                    | Trecharge Threshold voltage  | $V_{BAT}$ falling, $V_{BATREG}$ = 4.2V, $V_{RCH}$ = 200mV setting  |                                       | 200           |                      | mV   |
| R <sub>PMID_PD</sub>                     | PMID pull-down resistance  | V <sub>PMID</sub> = 3.6V   |                                       | 25            |                      | Ω    |
| VDD                                      |  |  |                                       |               |                      |      |
| $V_{DD}$                                 | VDD LDO output voltage   |  |                                       | 1.8           |                      | V    |
| LS/LDO                                   |  |  |                                       |               |                      |      |
|  | Input voltage range for Load switch Mode                                     |  | 0.8                                   |               | 5.5                  | V    |
| V <sub>INLS</sub>                        | Input voltage range for LDO Mode   |  | 2.2 or<br>V <sub>LDO</sub> +<br>500mV |               | 5.5                  | V    |
|  | LDO programmable output voltage range  |  | 0.6                                   |               | 3.7                  | V    |
| $V_{LDO}$                                |  | T <sub>.1</sub> = 25°C   | -2                                    |               | 2                    | %    |
| LDO                                      | LDO output accuracy  | V <sub>LDO</sub> = 1.8V, V <sub>INLS</sub> =3.6V. I <sub>LOAD</sub> = 1mA                                    | -3                                    |               | 3                    | %    |
| ΔV <sub>OUT</sub> /<br>ΔΙ <sub>ΟUT</sub> | DC Load Regulation   | 0°C < T <sub>J</sub> < 85°C, 1 mA < I <sub>OUT</sub> < 150mA,<br>V <sub>LDO</sub> = 1.8V                     |                                       | 1.2           |                      | %    |
| ΔV <sub>OUT</sub> /<br>ΔV <sub>IN</sub>  | DC Line Regulation   | 0°C < T <sub>J</sub> < 85°C, Over V <sub>INLS</sub> range, I <sub>OUT</sub> = 100mA, V <sub>LDO</sub> = 1.8V |                                       | 0.5           |                      | %    |
| R <sub>DOSN_LD</sub><br>o                | Switch On resistance   | V <sub>INLS</sub> = 3.6V   |                                       | 250           | 450                  | mΩ   |
| R <sub>DSCH_LS</sub>                     | Discharge FET On-resistance for LS   | V <sub>INLS</sub> = 3.6V   |                                       | 40            |                      | Ω    |
| I <sub>OCL_LDO</sub>                     | Output Current Limit   | V <sub>LS/LDO</sub> = 0V   | 200                                   | 300           |                      | mA   |
| I <sub>IN LDO</sub>                      | LDO VINLS quiescent current in LDO mode                                      | V <sub>BAT</sub> = V <sub>INLS</sub> =3.6V   |                                       | 0.9           |                      | μΑ   |
|  | OFF State Supply Current   | V <sub>BAT</sub> = V <sub>INLS</sub> =3.6V   |                                       | 0.25          |                      | μΑ   |
| BATTERY                                  | PACK NTC MONITOR   |  |                                       |               |                      |      |
| V <sub>HOT</sub>                         | High temperature threshold   | V <sub>TS</sub> falling, -10°C < T <sub>J</sub> < 85°C   | 0.182 <sup>(1)</sup>                  | 0.185         | 0.189 <sup>(1)</sup> | V    |
| V <sub>WARM</sub>                        | Warm temperature threshold   | V <sub>TS</sub> falling, -10°C < T <sub>J</sub> < 85°C   | 0.262(1)                              | 0.265         | 0.268(1)             | V    |
| V <sub>COOL</sub>                        | Cool temperature threshold   | V <sub>TS</sub> rising, -10°C < T <sub>J</sub> < 85°C  | 0.510 <sup>(1)</sup>                  | 0.514         | 0.518 <sup>(1)</sup> | V    |
| V <sub>COLD</sub>                        | Cold temperature threshold   | V <sub>TS</sub> rising, -10°C < T <sub>J</sub> < 85°C  | 0.581 <sup>(1)</sup>                  | 0.585         | 0.589(1)             | V    |
| V <sub>OPEN</sub>                        | TS Open threshold  | V <sub>TS</sub> rising, -10°C < T <sub>J</sub> < 85°C  |                                       | 0.9           |                      | V    |
| V <sub>HYS</sub>                         | Threshold hysteresis   |  |                                       | 4.7           |                      | mV   |



# **6.5 Electrical Characteristics (continued)**

 $V_{IN}$  = 5V,  $V_{BAT}$  = 3.6V.  $T_J$  = 25°C unless otherwise noted.

|                            | PARAMETER   | TEST CONDITIONS   | MIN                       | TYP  | MAX  | UNIT |
|----------------------------|---|---|---------------------------|------|--|------|
| I <sub>TS_BIAS</sub>       | TS bias current   | -10°C < T <sub>J</sub> < 85°C   | 78.4                      | 80   | 81.6   | μA   |
| PROTEC                     | TION  |   |                           |      |  |      |
| V                          | IN active threshold voltage                                 | V <sub>IN</sub> rising  |                           | 3.4  |  | V    |
| $V_{UVLO}$                 | in active tilleshold voltage                                | V <sub>IN</sub> falling   |                           | 3.25 | 81.6 μ.  3 \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ | V    |
|                            | Battery undervoltage Lockout Threshold Voltage              | Programmable range, 150 mV Hysteresis                                   | 2.4                       |      | 3  | V    |
| $V_{BATUVLO}$              | Accuracy  |   | -3                        |      | 3  | %    |
|                            | Battery undervoltage Lockout Threshold Voltage at Power Up  | V <sub>BAT</sub> rising, V <sub>IN</sub> = 0V, T <sub>J</sub> = 25°C    |                           | 3.15 |  | V    |
| V <sub>SLP_ENT</sub><br>RY | Sleep Entry Threshold (V <sub>IN</sub> - V <sub>BAT</sub> ) | 2.0V < V <sub>BAT</sub> < V <sub>BATREG</sub> , V <sub>IN</sub> falling |                           | 80   |  | mV   |
| V <sub>SLP_EXIT</sub>      | Sleep Exit Threshold (V <sub>IN</sub> - V <sub>BAT</sub> )  | 2.0V < V <sub>BAT</sub> < V <sub>BATREG</sub>                           |                           | 130  |  | mV   |
| V <sub>OVP</sub>           | Input Supply Over Voltage Threshold                         | V <sub>IN</sub> rising  | 5.35                      | 5.5  | 5.8  | V    |
| VOVP                       | input Supply Over voltage Threshold                         | V <sub>IN</sub> falling (125mV hysteresis)                              |                           | 5.4  |  | V    |
| I <sub>BAT_OCP</sub>       | Battery Over Current Threshold Programmable range           | I <sub>BAT_OCP</sub> increasing   | 1200                      |      | 1600   | mA   |
| _                          | Current Limit Accuracy                                      |   | -30                       |      | 30   | %    |
| T <sub>SHUTDO</sub><br>WN  | Thermal shutdown trip point                                 |   |                           | 125  |  | °C   |
| T <sub>HYS</sub>           | Thermal shutdown trip point hysteresis                      |   |                           | 15   |  | °C   |
| I <sup>2</sup> C INTER     | RFACE (SCL and SDA)   |   |                           |      |  |      |
|                            | I <sup>2</sup> C Frequency                                  |   | 100                       |      | 400  | kHz  |
| V <sub>IL</sub>            | Input Low threshold level                                   | V <sub>PULLUP</sub> = V <sub>IO</sub> = 1.8V                            |                           |      |  | V    |
| V <sub>IH</sub>            | Input High Threshold level                                  | V <sub>PULLUP</sub> = V <sub>IO</sub> = 1.8V                            | 0.75 *<br>V <sub>IO</sub> |      |  | V    |
| V <sub>OL</sub>            | Output Low threshold level                                  | V <sub>PULLUP</sub> = V <sub>IO</sub> = 1.8V, I <sub>LOAD</sub> = 5mA   |                           |      |  | V    |
| $I_{LKG}$                  | High-level leakage Current                                  | V <sub>PULLUP</sub> = V <sub>IO</sub> = 1.8V                            |                           |      | 1  | μΑ   |
| /MR INPU                   | JΤ  |   |                           |      |  |      |
| $R_{PU}$                   | Internal pull up resistance                                 |   | 90                        | 125  | 170  | kΩ   |
| $V_{IL}$                   | /MR Input Low threshold level                               | $V_{BAT} > V_{BUVLO}$   |                           |      | 0.3  | V    |
| /INT, /PG                  | OUTPUTS   |   |                           |      |  |      |
| V <sub>OL</sub>            | Output Low threshold level                                  | V <sub>PULLUP</sub> = V <sub>IO</sub> = 1.8V, I <sub>LOAD</sub> = 5mA   |                           |      |  | V    |
| I <sub>LKG</sub>           | /INT Hi level leakage Current                               | High Impedance, V <sub>PULLUP</sub> = V <sub>IO</sub> = 1.8V            |                           |      | 1  | μA   |
| /CE, /LP I                 | NPUTS   |   |                           |      |  |      |
| R <sub>PDOWN</sub>         | /CE pull down resistance                                    |   |                           | 900  |  | kΩ   |
| V <sub>IL</sub>            | Input Low threshold level                                   | V <sub>IO</sub> = 1.8V  |                           |      | 0.45   | V    |
| V <sub>IH</sub>            | /CE Input High Threshold level                              | V <sub>IO</sub> = 1.8V  | 1.35                      |      |  | V    |

#### (1) Based on Characterization Data

# 6.6 Timing Requirements

| PARAMETER                               | TEST CONDITIONS    | MIN | TYP MAX | UNIT |
|---|--------------------|-----|---------|------|
| BATTERY CHARGE TIMERS                   |                    |     |         |      |
| t <sub>MAXCHG</sub> Charge safety timer | Programmable range | 180 | 720     | min  |

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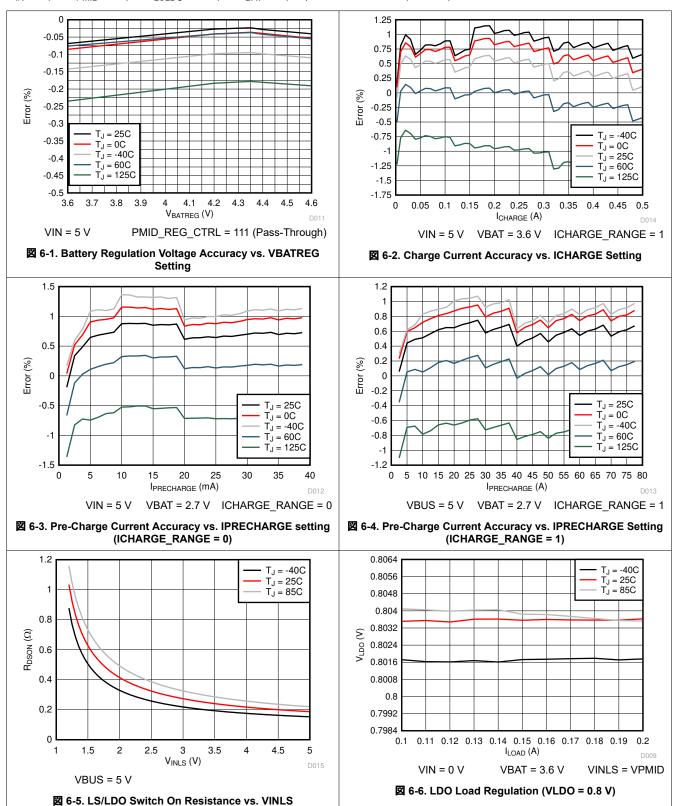
6.6 Timing Requirements (continued)

|  | PARAMETER  | TEST CONDITIONS                                   | MIN  | TYP    | MAX                 | UNI |
|--|--|---|------|--------|---------------------|-----|
| t <sub>PRECHG</sub>                    | Precharge safety timer   |   |      | 0.25 * | t <sub>MAXCHG</sub> |     |
| WATCHD                                 | OG TIMERS  |   |      |        | <u> </u>            |     |
| t <sub>WATCHDO</sub><br>G_SW           | SW Watchdog timer  |   | 25   | 50     |                     | s   |
| t <sub>HW_RESE</sub><br>T_WD           | HW reset watchdog timer  | HWRESET_14S_WD = 1                                |      |        | 14                  | S   |
| LDO                                    |  |   |      |        |                     |     |
| t <sub>ON_LDO</sub>                    | Turn ON time   | 100mA load, to 90% V <sub>LDO</sub>               |      | 500    |                     | μs  |
| t <sub>OFF_LDO</sub>                   | Turn OFF time  | 100mA load, to 10% V <sub>LDO</sub>               |      | 30     |                     | μs  |
| t <sub>PMID_LDO</sub><br>_DELAY        | Delay between PMID and LDO enable during power up                                  | Startup   |      | 20     |                     | ms  |
| PUSHBU                                 | TTON TIMERS (/MR)  |   | ·    |        | ·                   |     |
| t <sub>WAKE1</sub>                     | WAKE1 Timer. Timer for Ship Mode wake.   | MR_WAKE1_TIMER = 0                                | 106  | 125    | 144                 | ms  |
| t <sub>WAKE2</sub>                     | WAKE2 Timer. Time from /MR falling edge to INT being asserted.                     | MR_WAKE2_TIMER = 1                                | 1.7  | 2      | 2.3                 | s   |
| t <sub>RESET_W</sub><br>ARN            | RESET_WARN Timer. Time prior to HW<br>RESET or entering Shipmode with /MR<br>press | MR_RESET_WARN = 01                                | 0.85 | 1      | 1.15                | s   |
| t <sub>HW_RESE</sub><br>T              | Time from /MR Falling edge to HW<br>RESET or PMID falling for Shipmode<br>Entry    | MR_HW_RESET = 01                                  | 6.8  | 8      | 9.2                 | s   |
| t <sub>RESTART(</sub><br>AUTOWAKE<br>) | RESTART Timer. Time from /MR HW<br>Reset to PMID power up                          | AUTOWAKE = 01                                     | 1.05 | 1.2    | 1.35                | s   |
| PROTEC                                 | TION   |   | -    |        |                     |     |
| t <sub>DGL_SLP</sub>                   | Deglitch time for supply rising above $V_{SLP} + V_{SLP\_HYS}$                     |   |      | 120    |                     | μs  |
| t <sub>DGL_OVP</sub>                   | Deglitch time for V <sub>OVP</sub> Threshold                                       | VIN falling below V <sub>OVP</sub>                |      | 32     |                     | ms  |
| t <sub>DGL_OCP</sub>                   | Battery OCP deglitch time  |   |      | 30     |                     | μs  |
| t <sub>REC_SC</sub>                    | Recovery time, BAT Short Circuit during Discharge Mode                             |   |      | 250    |                     | ms  |
| t <sub>RETRY_SC</sub>                  | Retry window for PMID or BAT short circuit recovery                                |   |      | 2      |                     | s   |
| t <sub>DGL_SHT</sub><br>DWN            | Deglitch time, Thermal shutdown  | T <sub>J</sub> rising above T <sub>SHUTDOWN</sub> |      | 10     |                     | μs  |
| I2C INTE                               | RFACE  |   |      |        |                     |     |
| t <sub>WATCHDO</sub><br>G              | I <sup>2</sup> C interface reset timer for host                                    | When enabled                                      |      | 50     |                     | s   |
| t <sub>I2CRESET</sub>                  | I <sup>2</sup> C interface inactive reset timer                                    |   |      | 500    |                     | ms  |
| INPUT PI                               | NS (/CE and /LP)   |   |      |        |                     |     |
| t <sub>LP_EXIT_I</sub><br>2C           | Time for device to exit Low-power mode and allow I <sup>2</sup> C communication    | V <sub>IN</sub> = 0V.                             |      |        | 1                   | ms  |
|  |  |   |      |        |                     |     |



# 6.7 Typical Characteristics

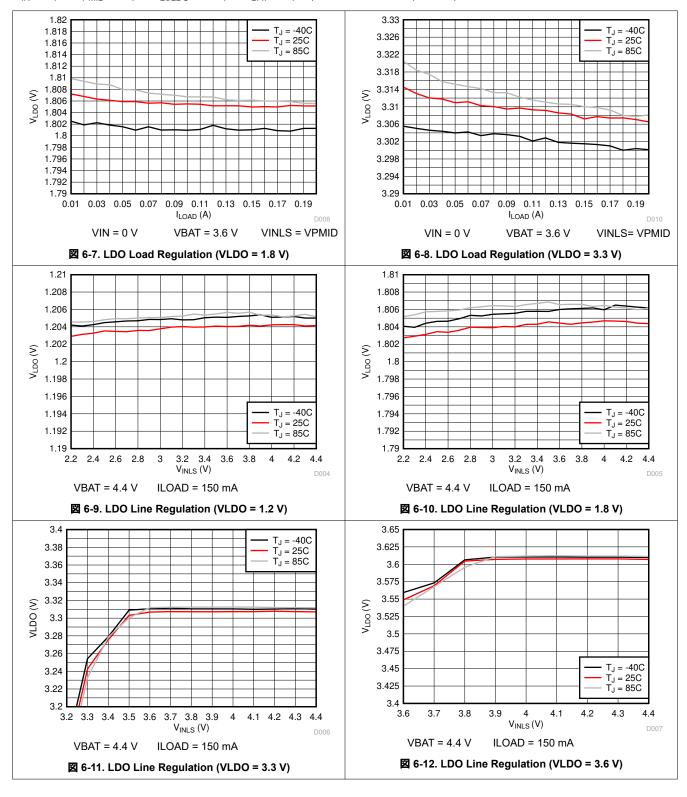
 $C_{IN}$  = 1  $\mu$ F,  $C_{PMID}$ = 10  $\mu$ F,  $C_{LSLDO}$  = 2.2  $\mu$ F,  $C_{BAT}$  = 1  $\mu$ F (unless otherwise specified)



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# **6.7 Typical Characteristics (continued)**

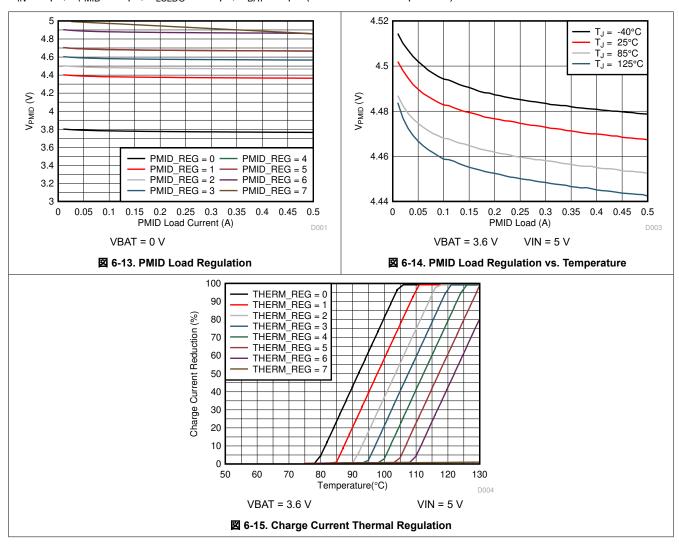
 $C_{IN}$  = 1  $\mu$ F,  $C_{PMID}$ = 10  $\mu$ F,  $C_{LSLDO}$  = 2.2  $\mu$ F,  $C_{BAT}$  = 1  $\mu$ F (unless otherwise specified)





# **6.7 Typical Characteristics (continued)**

 $C_{IN}$  = 1  $\mu$ F,  $C_{PMID}$ = 10  $\mu$ F,  $C_{LSLDO}$  = 2.2  $\mu$ F,  $C_{BAT}$  = 1  $\mu$ F (unless otherwise specified)



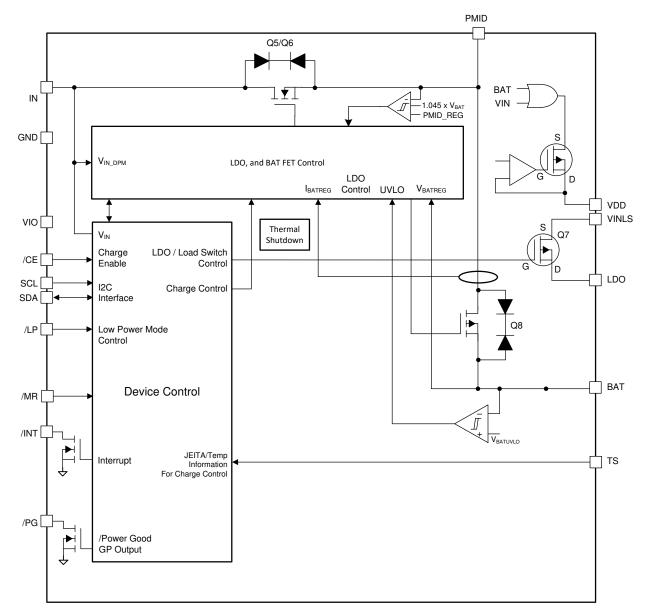


# 7 Detailed Description

#### 7.1 Overview

The BQ21061 IC is a highly programmable battery management device that integrates a 500-mA linear charger for single cell Li-lon batteries, a general purpose LDO that may be configured as a load switch, and a push-button controller. Through it's I<sup>2</sup>C interface the host may change charging parameters such as battery regulation voltage and charge current, and obtain detailed device status and fault information. The push-button controller allows the user to reset the system without any intervention from the host and wake up the device from Ship Mode.

## 7.2 Functional Block Diagram



#### 7.3 Feature Description

#### 7.3.1 Linear Charger and Power Path

The BQ21061 IC integrates a linear charger that allows the battery to be charged with a programmable charge current of up to 500 mA. In addition to the charge current, other charging parameters can be programmed

through I<sup>2</sup>C such as the battery regulation voltage, pre-charge current, termination current, and input current limit current.

The power path allows the system to be powered from PMID, even when the battery is dead or charging, by drawing power from IN pin. It also prioritizes the system load connected to PMID, reducing the charging current, if necessary, in order to support the load when input power is limited. If the input supply is removed and the battery voltage level is above V<sub>BATUVLO</sub>, PMID will automatically and seamlessly switch to battery power.

A more detailed description of the charger functionality is presented in the following sections of this document.

#### 7.3.1.1 Battery Charging Process

The following diagram summarizes the charging process of the BQ21061 charger.

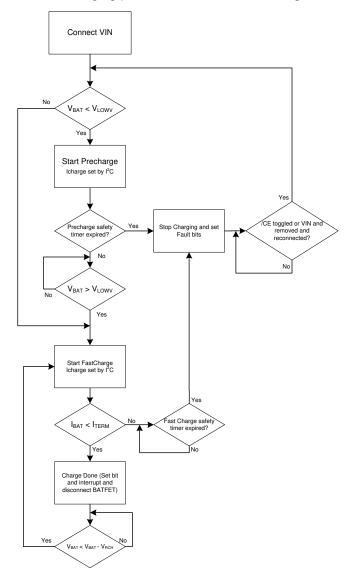


図 7-1. BQ21061 Charger Flow Diagram

When a valid input source is connected ( $V_{IN} > V_{UVLO}$  and  $V_{BAT} + V_{SLP} < V_{IN} < V_{OVP}$ ), the state of the  $\overline{CE}$  pin determines whether a charge cycle is initiated. When the  $\overline{CE}$  input is high and a valid input source is connected, the battery charge FET is turned off, preventing any kind of charging of the battery. A charge cycle is initiated when the CHARGE\_DISABLE bit is written to 0 and  $\overline{CE}$  pin in low.  $\frac{1}{2}$  7-1 shows the  $\overline{CE}$  pin and bit priority to enable/disable charging.

| 表 7-1. Charge Enable Function       | The second OF Diagram of OF Diagram |
|-------------------------------------|-------------------------------------|
| 表 /-1 (:narge Enable Ellection      | Infolian (ie Pin and (ie Bit        |
| TE 1-1. Offarge Effable I different |                                     |

| CE PIN | CHARGE _DISABLE BIT | CHARGING |
|--------|---------------------|----------|
| 0      | 0                   | Enabled  |
| 0      | 1                   | Disabled |
| 1      | 0                   | Disabled |
| 1      | 1                   | Disabled |

#### 

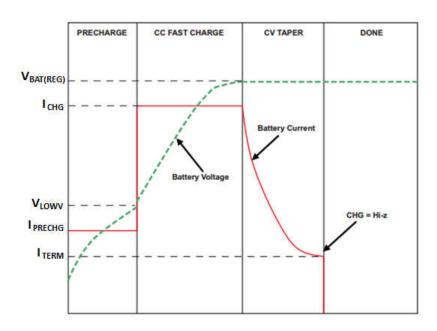


図 7-2. BQ21061 Typical Charge Cycle

During Pre-Charge, where the battery voltage is below the  $V_{LOWV}$  level, the battery will be charge with  $I_{PRECHARGE}$  current which can be programmed through  $I^2C$ . During pre-charge, the safety timer is set to 25% of the safety timer value during fast charge. Once the battery voltage reaches  $V_{LOWV}$ , the charger will then operate in Fast Charge Mode, charging the battery at  $I_{CHARGE}$  which may also be programmed through  $I_2C$ . Once the battery voltage approaches the  $V_{BATREG}$  level, the charging current starts tapering off as shown in  $\boxtimes$  7-2. Once the charging current reaches the termination current ( $I_{TERM}$ ) charging is stopped. Note that to ensure that the battery is charged to  $V_{BATREG}$  level, the regulated PMID voltage should be set to at least 200mV above  $V_{BATREG}$ . Termination is only enabled when the charger CV loop is active in fast charge operation. No termination will occur if the charge current reaches  $I_{TERM}$  while VINDPM or DPPM is active as well as the thermal regulation loop. Termination is also disabled when operating in the TS WARM region. The charger only goes to termination when the current drops to  $I_{TERM}$  due to the battery reaching the target voltage and not due to the charge current limitation imposed by the previously mentioned control loops

Whenever a change in the charge current setting is triggered, whether it occurs due to  $I^2C$  programming by the host, Pre-Charge/Fast Charge transition or JEITA TS control, the device will temporarily disable charging (for  $\sim 1$  ms) before updating the charge current value.

#### 7.3.1.2 JEITA and Battery Temperature Dependent Charging

The charger can be configured through I<sup>2</sup>C setting to provide JEITA support, automatically reducing the charging current and voltage depending on the battery temperature as monitored by an NTC thermistor connected to the BQ21061 TS pin. See セクション 7.3.11 for details.

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# 7.3.1.3 Input Voltage Based Dynamic Power Management (VINDPM) and Dynamic Power Path Management (DPPM)

The VINDPM loop prevents the input voltage from collapsing to a point where charging would be interrupted by reducing the current drawn by charger in order to keep  $V_{IN}$  from dropping below  $V_{IN\_DPM}$ . Once the IN voltage drops to  $V_{IN\_DPM}$ , the VINDPM loops will reduce the input current through the blocking FETs, to prevent the further drop of the supply voltage. The VINDPM function is disabled by default and may be enabled through I<sup>2</sup>C command. The  $V_{IN\_DPM}$  threshold is programmable through the I<sup>2</sup>C register from 4.2 V to 4.9 V in 100-mV steps.

On the other hand, the DPPM loop prevents the system output (PMID) from dropping below  $V_{BAT}$  + 200mV when the sum of the charge current and system load exceeds the BQ21061 input current limit setting. If PMID drops below the DPPM voltage threshold, the charging current is reduced. If PMID continues to drop after BATFET charging current is reduced to zero, the part will enter supplement mode when PMID falls below the supplement mode threshold ( $V_{BAT}$  -  $V_{BSUP1}$ ). NOte that DPPM function is disabled when PMID regulation is set to battery tracking.

When the device enters these modes, the charge current may be lower than the set value and the corresponding status bits and flags are set. If the 2X timer is set, the safety timer is extended while the loops are active. Additionally, termination is disabled.

# 7.3.1.4 Battery Supplement Mode

When the PMID voltage drops below the battery voltage by  $V_{BSUP1}$ , the battery supplements the system load. The battery stops supplementing the system load when the voltage on the PMID pin rises above the battery voltage by  $V_{BSUP2}$ . During supplement mode, the battery supplement current is not regulated, however, the Battery Over-Current Protection mechanism is active. Battery charge termination is disabled while in supplement mode.

#### 7.3.2 Protection Mechanisms

#### 7.3.2.1 Input Over-Voltage Protection

The input over-voltage protection protects the device and downstream components connected to PMID, and BAT against damage from over-voltage on the input supply. When  $V_{IN} > V_{OVP}$  an OVP fault is determined to exist. During the OVP fault, the device turns the input FET off, sends a single 128-µs pulse on  $\overline{INT}$ , and the VIN\_OVP\_FAULT FLAG and STAT bits are updated over I<sup>2</sup>C. Once the OVP fault is removed, the STAT bit is cleared and the device returns to normal operation. The FLAG bit is not cleared until it is read through I<sup>2</sup>C after the OVP condition no longer exists. The OVP threshold for the device is 5.5 V to allow operation from standard USB sources.

# 7.3.2.2 Safety Timer and I<sup>2</sup>C Watchdog Timer

At the beginning of the charge cycle, the device starts the safety timer. If charging has not terminated before the programmed safety time,  $t_{MAXCHG}$ , expires, charging is disabled. The pre-charge safety time,  $t_{PRECHG}$ , is 25% of  $t_{MAXCHG}$ . When a safety timer fault occurs, a single 128-µs pulse is sent on the  $\overline{INT}$  pin and the SAFETY\_TMR\_FAULT\_FLAG bit in the FLAG3 register is updated over  $I^2C$ . The  $\overline{CE}$  pin or input power must be toggled in order to reset the safety timer and exit the fault condition. Note that the flag bit will be reset when the bit is read by the host even if the fault has not been cleared. The safety timer duration is programmable using the SAFETY\_TIMER bits. When the safety timer is active, changing the safety timer duration resets the safety timer. The device also contains a 2X\_TIMER bit that doubles the timer duration to prevent premature safety timer expiration when the charge current is reduced by a high load on PMID (DPPM operation), VIN DPM, thermal regulation, or a NTC (JEITA) condition. When 2X\_TIMER function is enabled, the timer is allowed to run at half speed when any loop is active other than CC or CV.

In addition, the BQ21061 has a 50s watchdog timer which resets after every I<sup>2</sup>C transaction. This feature, which is enabled by default, resets all charger parameters registers to their default values when the timer expires.

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#### 7.3.2.3 Thermal Protection and Thermal Charge Current Foldback

In order to protect the device from damage due to overheating, the junction temperature of the die,  $T_J$ , is monitored. When  $T_J$  reaches  $T_{SHUTDOWN}$  the device stops operation and is turned off. The device resumes operation when  $T_J$  falls below  $T_{SHUTDOWN}$  by  $T_{HYS}$ .

During the charging process, the device will reduce the charging current at a rate of  $(0.04 \text{ x I}_{CHARGE})$ /°C once T<sub>J</sub> exceeds the thermal foldback threshold, T<sub>REG</sub> to prevent further heating. If the charge current is reduced to 0, the battery supplies the current needed to supply the PMID output. The thermal regulation threshold may be set through I<sup>2</sup>C by setting the THERM REG bits to the desired value.

The die junction temperature, T<sub>J</sub>, can be estimated based on the expected board performance using 式 1:

$$T_{J} = T_{A} + \theta_{JA} \times P_{DISS} \tag{1}$$

Where  $P_{DISS}$  is the total power dissipation in the IC. The  $\theta_{JA}$  is largely driven by the board layout. For more information about traditional and new thermal metrics, see the *Semiconductor and IC Package Thermal Metrics Application Report*. Under typical conditions, the time spent in this state is very short.

#### 7.3.2.4 Battery Short and Over Current Protection

In order to protect the device from over current and prevent excessive battery discharge current, the BQ21061 detects if the current on the battery FET exceeds  $I_{BAT\_OCP}$ . If the short circuit limit is reached for the deglitch time ( $t_{DGL\_OCP}$ ), the battery discharge FET is turned off and start operating in hiccup mode, re-enabling the BATFET  $t_{REC\_SC}$  (250 ms) after being turned off by the over-current condition. If the over-current condition is triggered upon retry for 3 to 7 consecutive times, the BATFET will then remain off until the part is reset or until Vin is connected and valid. If the over-current condition and hiccup operation occurs while in supplement mode where VIN is already present, VIN must be toggled in order for BATFET to be enabled and start another detection cycle.

In the case where the battery is suddenly shorted while charging and VBAT drops below  $V_{SHORT}$ , a fast comparator quickly reduces the charge current to  $I_{PRECHARGE}$  preventing fast charge current to be momentarily injected to the battery while shorted.

#### 7.3.2.5 PMID Short Circuit

A short on the PMID pin is detected when the PMID voltage drops below 1.6 V (PMID short threshold). PMID short threshold has a 200-mV hysteresis. When this occurs, the input FET temporarily disconnects IN for up to 200 µs to prevent stress on the device if a sudden short condition happens, before allowing a softstart on the PMID output.

#### 7.3.3 VDD LDO

The device integrates a low current always-on LDO that serves as the digital I/O supply to the device. This LDO is supplied by VIN or by BAT. The VDD LDO will remain on through all power states with the exception of Ship Mode.

#### 7.3.4 Load Switch/LDO Output and Control

The device integrates a low Iq load switch which can also be used as a regulated output. The LDO/LS has a dedicated input pin VINLS and can support up to 150 mA of load current.

The LS/LDO may be enabled/disabled through  $I^2C$ . The output voltage is programmable using the LS\_LDO bits in the registers. To limit voltage drop or voltage transients, a small ceramic capacitor must be placed close to VINLS pin.

表 7-2. LDO Mode Control

| I2C EN_LS_LDO | LS_CONFIG | LS/LDO OUTPUT |
|---------------|-----------|---------------|
| 0             | 0         | Pulldown      |
| 0             | 1         | Pulldown      |

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## 表 7-2. LDO Mode Control (continued)

| I2C EN_LS_LDO | LS_CONFIG | LS/LDO OUTPUT |
|---------------|-----------|---------------|
| 1             | 0         | LDO           |
| 1             | 1         | Load Switch   |

The current capability of the LDO will depend on the VINLS input voltage and the programmed output voltage. When the LS/LDO output is disabled through the register, an internal pull-down will discharge the output. The LDO has output current limit protection, limiting the output current in the event of a short in the output. When the LDO output current limit trips and is active for at least 1 ms, the device will set a flag and send an interrupt to the host. The host must take action to disable the LDO if desired. The LDO may be set to operate as a load switch by setting the LS\_SWITCH\_CONFG bit. Note that in order to change the configuration the LDO must be disabled first, then the LS\_SWITCH\_CONFG bit is set for it to take effect. This is not the case when updating the LDO output voltage which can be done on the fly without the need of disabling the LDO first.

#### 7.3.5 PMID Power Control

The BQ21061 offers the option to control PMID through the I $^2$ C PMID\_MODE bits. These bits can force PMID to be supplied by BAT instead of IN, even if  $V_{IN} > V_{BAT} + V_{SLP}$ . They can also disconnect PMID, pulling it down or leaving it floating. See  $\frac{1}{8}$  7-30 for details.

### 7.3.6 System Voltage (PMID) Regulation

The BQ21061 has a regulated system voltage output (PMID) that is programmable through  $I^2C$ . PMID regulation is only active when the adapter is connected and  $V_{IN} > V_{UVLO}$ ,  $V_{IN} > V_{BAT} _ V_{SLP}$  and  $V_{IN} < V_{OVP}$ . In Battery Tracking operation (PMID\_REG\_CTRL = 000), the PMID voltage will be regulated to about 4.7% over battery level ( $V_{PMID} = V_{BAT} \times 1.047$ ) or 3.8 V, whichever is higher. Note that the PMID regulation target should be set to be at least 200mV higher than  $V_{BATREG}$ .

#### 7.3.7 MR Wake and Reset Input

The  $\overline{\text{MR}}$  input has three main functions in the BQ21061. First, it serves as a means to wake the device from Ship Mode. Second, it serves as a short button press detector, sending an interrupt to the host when the button driving the  $\overline{\text{MR}}$  pin has been pressed for a given period of time. This allows the implementation of different functions in the end application such as menu selection and control. And finally it serves as a means to get the BQ21061 to reset the system by performing a power cycle (shut down PMID and automatically powering it back on) or go to Ship Mode after detecting a long button press. The timing for the short and long button press duration is programmable through I<sup>2</sup>C for added flexibility. Note that if a specific timer duration is changed through I<sup>2</sup>C while that timer is active and has not expired, the new programmed value will be ignored until the timer expires and/or is reset by  $\overline{\text{MR}}$ . The  $\overline{\text{MR}}$  input has an internal pull-up to BAT.

#### 7.3.7.1 MR Wake or Short Button Press Functions

There are two programmable wake or short button press timers, WAKE1 and WAKE2. When the  $\overline{\text{MR}}$  pin is held low for  $t_{\text{WAKE1}}$  the device sends an interrupt (128  $\mu s$  active low pulse in the  $\overline{\text{INT}}$  pin) and sets the MRWAKE1\_TIMEOUT flag when it expires. If the  $\overline{\text{MR}}$  pin continues to be driven low after WAKE1 and the WAKE2 timer expires, the BQ21061 sends a second interrupt and sets the MRWAKE2\_TIMOUT flag. WAKE1 is used as the timer to wake the device from ship mode. WAKE2's only function is to send the interrupt and has no effect on other BQ21061 functions. These flags are not cleared until they have been read by the host. Note that interrupts are only sent when the flags are set and the flags must be cleared in order for another interrupt to be sent upon  $\overline{\text{MR}}$  press. The timer durations can be set through the MR\_WAKEx\_TIMER bits in the MRCTRL Register section.

One of the main  $\overline{MR}$  functions is to wake the device from Ship Mode when the  $\overline{MR}$  is asserted. The device will exit the Ship Mode when the  $\overline{MR}$  pin is held low for at least  $t_{WAKE1}$ . Immediately after the  $\overline{MR}$  is asserted, VDD will be enabled and the digital will start the WAKE counter. If the  $\overline{MR}$  signal remains low until after the WAKE1 timer expires, the device will power up PMID and LDO (If enabled) completing the exit from the ship mode. If the  $\overline{MR}$  signal goes high before the WAKE1 timer expires, the device will go back to the Ship Mode operation, never powering up PMID or the LDO. Note that if the  $\overline{MR}$  pin remains low after exiting Ship Mode the wake interrupts

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will not be sent and the long button press functions like HW reset will not occur until the  $\overline{MR}$  pin is toggled. In the case where a valid  $V_{IN}$  ( $V_{IN} > V_{UVLO}$ ) is connected prior to WAKE2 timer expiring, the device will exit the ship mode immediately regardless of the  $\overline{MR}$  or wake timer state.  $\boxtimes$  7-3 and  $\boxtimes$  7-4 show these different scenarios.

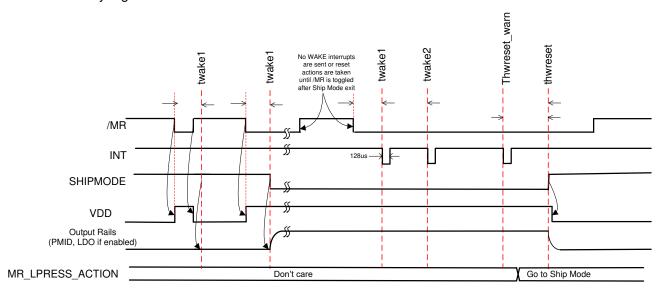


図 7-3. MR Wake from Ship Mode (MR\_LPRESS\_ACTION = Ship Mode, VIN not valid)

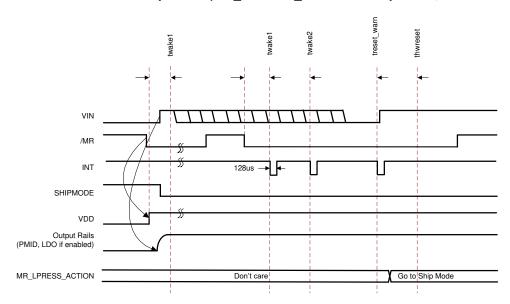


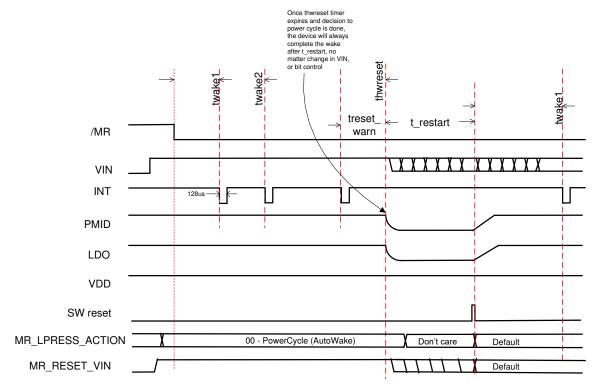
図 7-4. MR Wake from Ship Mode – VIN Dependencies

# 7.3.7.2 MR Reset or Long Button Press Functions

The BQ21061 device may be configured to perform a system hardware reset (Power Cycle/Autowake), go into Ship Mode, or simply do nothing after a long button press (for example, when the  $\overline{\text{MR}}$  pin is driven low until the MR\_HW\_RESET timer expires). The action taken by the device when the timer expires is configured through the MR\_LPRESS\_ACTION bits in the ICCTRL1 Register section. Once the MR\_HW\_RESET timer expires the device immediately performs the operation set by the MR\_LPRESS\_ACTION bits. The BQ21061 sends an interrupt to the host when the device detects that  $\overline{\text{MR}}$  has been pressed for a period that is within  $t_{\text{HW}_{\text{RESET}_{\text{WARN}}}}$  from reaching  $t_{\text{HW}_{\text{RESET}}}$ . This may warn the host that the button has been pressed for a period close to  $t_{\text{HW}_{\text{RESET}}}$  which would trigger a HW Reset or used as another button press timer interrupt like the WAKE1 and WAKE2 timers. This interrupt is sent before the MR\_HW\_RESET timer expires and sets the MRRESET\_WARN flag. The  $t_{\text{RESET}_{\text{WARN}}}$  may be set through  $t_{\text{LP}_{\text{RESET}}}$  by the MR\_RESET\_WARN bits in the

MRCTRL register. The host may change the reset behavior at any time after  $\overline{\text{MR}}$  going low and prior to the MR\_HW\_RESET timer expiring. It may not change it however from another behavior to a HW reset (Power Cycle/Autowake) since a HW reset can be gated by other condition requirements, such as valid VIN presence (controlled by MR\_RESET\_VIN bit), throughout the whole duration of the button press. This flexibility allows the host to abort any reset or power shutdown to the system by overriding a long button press command.

A HW reset may also be started by setting the HW\_RESET bit. Note that during a HW reset , VDD remains on.



☑ 7-5. MR Wake and Reset Timing with VIN Present or BAT Active Mode When MR\_LPRESS\_ACTION = 00

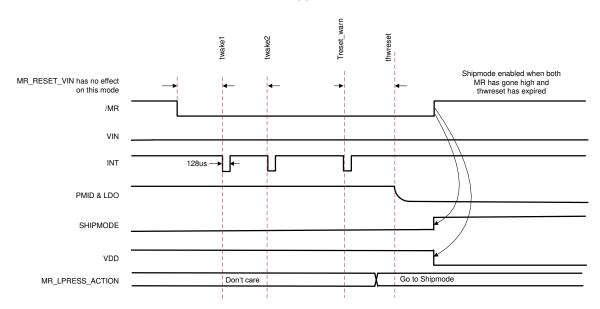


図 7-6. MR Wake and Reset Timing Active Mode When MR\_LPRESS\_ACTION = 1x (Ship Mode) and Only BAT is Present

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English Data Sheet: SLUSDU0

#### 7.3.8 14-Second Watchdog for HW Reset

The BQ21061 integrates a 14-second watchdog timer that makes the BQ21061 perform a HW reset/power cycle if no  $I^2C$  transaction is detected within 14 seconds of a valid adapter being connected. If the adapter is connected and the host responds with an  $I^2C$  transaction before the 14-second watchdog window expires, the part continues in normal operation. The 14-second watchdog is disabled by default and may be enabled through  $I^2C$  by setting the HWRESET 14S WD bit.  $\boxtimes$  7-7 shows the basic functionality of this feature.

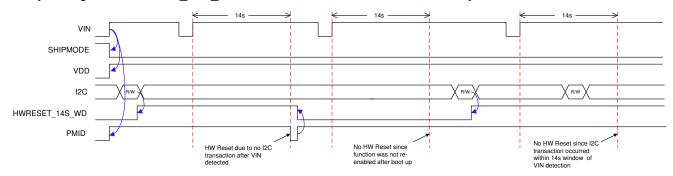


図 7-7. 14-Second Watchdog for HW Reset Behavior

## 7.3.9 Faults Conditions and Interrupts (INT)

The device contains an open-drain output that signals an interrupt and is valid only after the device has completed start-up into a valid state. If the part starts into a fault, interrupts will not be sent. The  $\overline{\text{INT}}$  pin is normally in high impedance and is pulled low for 128 µs when an interrupt condition occurs. When a fault or status change occurs or any other condition that generates an interrupt such as CHARGE\_DONE, a 128-µs pulse (interrupt) is sent on  $\overline{\text{INT}}$  to notify the host. All interrupts may be masked through  $I^2C$ . If the interrupt condition occurs while the interrupt is masked an interrupt pulse will not be sent. If the interrupt is unmasked while the fault condition is still present, an interrupt pulse will not be sent until the  $\overline{\text{INT}}$  trigger condition occurs while unmasked.

#### 7.3.9.1 Flags and Fault Condition Response

表 7-3 below details the BQ21061 behavior when a fault condition occurs.

#### 表 7-3. Interrupt Triggers and Fault Condition Response

| FAULT / FLAG           | DESCRIPTION  | INTERRUPT<br>TRIGGER<br>BASED ON<br>STATUS BIT<br>CHANGE | CHARGER<br>BEHAVIOR  | CHARGER SAFETY<br>TIMER      | PMID BEHAVIOR   |
|------------------------|--|--|--|------------------------------|---|
| CHRG_CV_FLAG           | Set when charger<br>enters Constant<br>Voltage operation | Rising Edge  | Enabled  | No effect                    | IN powered if V <sub>IN</sub> is valid                          |
| CHARGE_DONE_FLA<br>G   | Set when charger reaches termination                     | Rising Edge  | Paused- Charging resumes with VIN or CE toggle or when V <sub>RCH</sub> is reached | Reset                        | IN powered if V <sub>IN</sub> is valid                          |
| IINLIM_ACTIVE_FLAG     | Set when Input Current<br>Limit loop is active           | Rising Edge  | Enabled. Reduced charge current.   | Doubled if option is enabled | IN powered VIN powered unless supplement mode condition is met. |
| VDPPM_ACTIVE_FLA       | Set when DPPM loop is active                             | Rising Edge  | Enabled. Reduced charge current.   | Doubled if option is enabled | VIN powered unless supplement mode condition is met.            |
| VINDPM_ACTIVE_FL<br>AG | Set when VINDPM loop is active                           | Rising Edge  | Enabled. Reduced charge current.   | Doubled if option is enabled | VIN powered unless supplement mode condition is met.            |



表 7-3. Interrupt Triggers and Fault Condition Response (continued)

| æ 7-3. Interrupt ringgers and Fault Condition Response (Continued) |  |  |   |                                 |  |
|--|--|--|---|---------------------------------|--|
| FAULT / FLAG   | DESCRIPTION  | INTERRUPT<br>TRIGGER<br>BASED ON<br>STATUS BIT<br>CHANGE | CHARGER<br>BEHAVIOR                                 | CHARGER SAFETY<br>TIMER         | PMID BEHAVIOR  |
| THERMREG_ACTIVE  | Set when Thermal<br>Charge Current<br>Foldback (Thermal<br>Regulation) loop is<br>active | Rising Edge  | Enabled. Reduced charge current.                    | Doubled if option is<br>enabled | VIN powered unless<br>supplement mode<br>condition is met.                 |
| VIN_PGOOD_FLAG   | Set when VIN changes<br>PGOOD status   | Rising and<br>Falling Edge                               | If VIN_PGOOD_STAT is low, charging is disabled.     | Reset                           | VIN powered (if<br>VIN_PGOOD_STAT<br>=1) unless<br>PMID_MODE is not<br>00. |
| VIN_OVP_FAULT_FL<br>AG   | Set when V <sub>IN</sub> > V <sub>OVP</sub>  | Rising Edge  | Charging is paused<br>until condition<br>disappears | Reset                           | BAT powered  |
| BAT_OCP_FAULT_FL<br>AG   | Set when I <sub>BAT</sub> > I <sub>BATOCP</sub>  | Rising Edge  | Disabled (BAT only condition)                       | N/A                             | Disconnect BAT   |
| BAT_UVLO_FAULT_F<br>LAG  | Set when V <sub>BAT</sub> < V <sub>BATUVLO</sub>   | Rising Edge  | Enabled   | No effect                       | IN powered of V <sub>IN</sub> is valid                                     |
| TS_COLD_FLAG   | Set when V <sub>TS</sub> > V <sub>TS_COLD</sub>  | Rising Edge  | Charging paused until condition is cleared          | Paused                          | IN powered of V <sub>IN</sub> is valid                                     |
| TS_COOL_FLAG   | Set when V <sub>TS_COLD</sub> > V <sub>TS</sub> > V <sub>TS_COOL</sub>                   | Rising Edge  | Enabled. Reduced charge current.                    | Doubled if option is enabled    | IN powered of V <sub>IN</sub> is valid                                     |
| TS_WARM_FLAG   | Set when V <sub>TS_HOT</sub> < V <sub>TS</sub> < V <sub>TS_WARM</sub>                    | Rising Edge  | Enabled. Reduce battery regulation voltage.         | No effect                       | IN powered of V <sub>IN</sub> is valid                                     |
| TS_HOT_FLAG  | Set when V <sub>TS</sub> < V <sub>HOT</sub>  | Rising Edge  | Charging paused until condition is cleared          | Paused                          | IN powered of V <sub>IN</sub> is valid                                     |
| TS_OPEN_FLAG   | Set when V <sub>TS</sub> > V <sub>TS_OPEN</sub>  | Rising Edge  | Charging is paused<br>until condition<br>disappears | Paused                          | N/A  |
| WD_FAULT_FLAG  | Set when I <sup>2</sup> C watchdog timer expires   | Rising Edge  | Enabled   | N/A                             | N/A  |
| SAFETY_TMR_FAULT<br>_FLAG  | Set when safety Timer expires. Cleared after VIN or CE toggle                            | Rising Edge  | Disabled until VIN or<br>CE toggle                  | Reset after flag is cleared     | IN powered of V <sub>IN</sub> is valid                                     |
| LS_LDO_OCP_FAULT<br>_FLAG  | Set when LDO output current exceeds OCP condition  | Rising Edge  | N/A   | N/A                             | N/A  |
| MRWAKE1_TIMEOUT<br>_FLAG   | Set when MR is low for at least t <sub>WAKE1</sub>                                       | Rising Edge  | N/A   | N/A                             | N/A  |
| MRWAKE2_TIMEOUT<br>_FLAG   | Set when MR is low for at least t <sub>WAKE2</sub>                                       | Rising Edge  | N/A   | N/A                             | N/A  |
| MRRESET_WARN_FL<br>AG  | Set when MR is low for at least t <sub>RESETWARN</sub>                                   | Rising Edge  | N/A   | N/A                             | N/A  |
| TSHUT  | No flag. Die<br>temperature exceeds<br>thermal shutdown<br>threshold is reached          | N/A  | Disabled  | Disabled                        | Disabled   |

# 7.3.10 Power Good (PG) Pin

The  $\overline{PG}$  pin is an open-drain output that by default indicates when a valid IN supply is present. It may also be configured to be a general purpose output (GPO) controlled through I<sup>2</sup>C or to be a level shifted version of the

 $\overline{MR}$  input signal. Connect  $\overline{PG}$  to the desired logic voltage rail using a 1-kΩ to 100-kΩ resistor, or use with an LED for visual indication. See 表 7-30 for details.

#### 7.3.11 External NTC Monitoring (TS)

The I<sup>2</sup>C interface allows the user to easily implement the JEITA standard for systems where the battery pack thermistor is monitored by the host. Additionally, the device provides a flexible voltage based TS input for monitoring the battery pack NTC thermistor. The voltage at TS is monitored to determine that the battery is at a safe temperature during charging. The TS pin is not biased continuously, instead it is biased only when the voltage at the pin is being sampled (for about 25ms in 225ms intervals when VIN is present. Note that the TS biasing cannot be disabled when VIN is present.

The part can be configured to meet JEITA requirements or a simpler HOT/COLD function only. Additionally, the TS charger control function can be disabled. To satisfy the JEITA requirements, four temperature thresholds are monitored: the cold battery threshold, the cool battery threshold, the warm battery threshold, and the hot battery threshold. These temperatures correspond to the  $V_{COLD}$ ,  $V_{COOL}$ ,  $V_{WARM}$ , and  $V_{HOT}$  thresholds in the Electrical Characteristics table. Charging and safety timers are suspended when  $V_{TS} < V_{HOT}$  or  $V_{TS} > V_{COLD}$ . When  $V_{COOL} < V_{TS} < V_{COLD}$ , the charging current is reduced to the value programmed in the TS\_FASTCHGCTRL register. Note that the current steps for fast charge in the COOL region, just as those in normal fast charge, are multiples of the fast charge LSB value (1.25 mA by default). So in the case where the calculated scaled down current for the COOL region falls in between charge current steps, the device will round down the charge current to the nearest step. For example, if the fast charge current is set for 15 mA (ICHG = 1100) and TS\_FASTCHARGE =111 (0.125\*ICHG), the charge current in the COOL region will be 1.25 mA instead of the calculated 1.85 mA.

When  $V_{HOT} < V_{TS} < V_{WARM}$ , the battery regulation voltage is reduced to the value programmed in the TS FASTCHGCTRL register.

Regardless of whether the part is configured for JEITA, HOT/COLD, or disabled, when a TS fault occurs, a 128µs pulse is sent on the INT output, and the FAULT bits of the register are updated over I<sup>2</sup>C. The FAULT bits are not cleared until they are read over I<sup>2</sup>C. This allows the host processor to take action if a different behavior than the pre-set function is needed. Alternately, the TS pin voltage can be read by the host if VIN is present or when BAT is present, so the appropriate action can be taken by the host.

#### 7.3.11.1 TS Thresholds

The BQ21061 monitors the TS voltage and sends an interrupt to the host whenever it crosses the  $V_{HOT}$ ,  $V_{WARM}$ ,  $V_{COOL}$  and  $V_{COLD}$  thresholds which correspond to different temperature thresholds based on the NTC resistance and biasing. These thresholds may be adjusted through I<sup>2</sup>C by the host. The device will also disable charging if TS pin exceeds the  $V_{TS\ OPEN}$  threshold.

The TS biasing circuit is shown in  $\boxtimes$  7-8. Note that the respective V<sub>TS</sub> for T<sub>COLD</sub> (0°C), T<sub>COOL</sub> (10°C), T<sub>WARM</sub> (45°C) and T<sub>HOT</sub> (60°C) changes for every NTC, therefore the threshold values may need to be adjusted through I<sup>2</sup>C based on the supported NTC type.



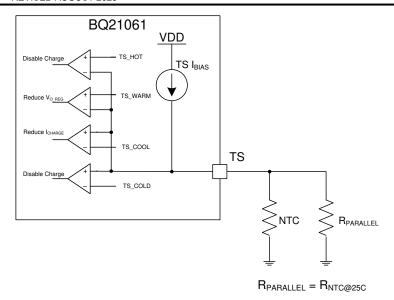


図 7-8. TS Bias Functional Diagram

The BQ21061 supports by default the following thresholds for a 10-K $\Omega$  NTC.

**TEMPERATURE THRESHOLD** VTS (V) (°C) Open >0.9 Cold 0 0.585 Cool 10 0.514 Warm 45 0.265 Hot 60 0.185

表 7-4. TS Thresholds for 10-KΩ Thermistor with 3380 B-Constant

#### 7.3.12 I<sup>2</sup>C Interface

The BQ21061 device uses a fully compliant I<sup>2</sup>C interface to program and read control parameters, status bits, and so on. I<sup>2</sup>C is a 2-wire serial interface developed by Philips Semiconductor (see I<sup>2</sup>C-Bus Specification, Version 2.1, January 2000). The bus consists of a data line (SDA) and a clock line (SCL) with pull-up structures. When the bus is idle, both SDA and SCL lines are pulled high. All the I<sup>2</sup>C compatible devices connect to the I<sup>2</sup>C bus through open drain I/O pins, SDA and SCL. A master device, usually a micro-controller or a digital signal processor, controls the bus. The master is responsible for generating the SCL signal and device addresses. The master also generates specific conditions that indicate the START and STOP of data transfer. A slave device receives and/or transmits data on the bus under control of the master device.

The BQ21061 works as a slave and supports the following data transfer modes, as defined in the I<sup>2</sup>C Bus Specification: standard mode (100 kbps) and fast mode (400 kbps). The interface adds flexibility to the battery charge solution, enabling most functions to be programmed to new values depending on the instantaneous application requirements.

Register contents remain intact as long as VBAT or VIN voltages remains above their respective UVLO levels.

The data transfer protocol for standard and fast modes is exactly the same; therefore, they are referred to as the F/S-mode in this document. The BQ21061 device 7-bit address is 0×6B (shifted 8-bit address is 0xD6).

#### 7.3.12.1 F/S Mode Protocol

The master initiates data transfer by generating a start condition. The start condition is when a high-to-low transition occurs on the SDA line while SCL is high, as shown in  $\boxtimes$  7-9. All I<sup>2</sup>C-compatible devices should recognize a start condition.

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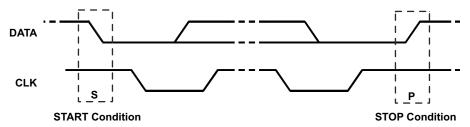


図 7-9. START and STOP Condition

The master then generates the SCL pulses, and transmits the 8-bit address and the read/write direction bit R/W on the SDA line. During all transmissions, the master ensures that data is valid. A valid data condition requires the SDA line to be stable during the entire high period of the clock pulse (see  $\boxtimes$  7-10). All devices recognize the address sent by the master and compare it to their internal fixed addresses. Only the slave device with a matching address generates an acknowledge (see  $\boxtimes$  7-11) by pulling the SDA line low during the entire high period of the ninth SCL cycle. Upon detecting this acknowledge, the master knows that communication link with a slave has been established.

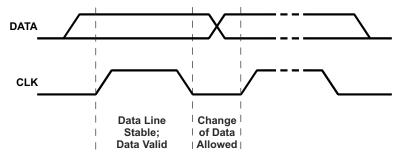


図 7-10. Bit Transfer on the Serial Interface

The master generates further SCL cycles to either transmit data to the slave (R/W bit 1) or receive data from the slave (R/W bit 0). In either case, the receiver needs to acknowledge the data sent by the transmitter. So an acknowledge signal can either be generated by the master or by the slave, depending on which one is the receiver. The 9-bit valid data sequences consisting of 8-bit data and 1-bit acknowledge can continue as long as necessary. To signal the end of the data transfer, the master generates a stop condition by pulling the SDA line from low to high while the SCL line is high (see  $\boxtimes$  7-9). This releases the bus and stops the communication link with the addressed slave. All I<sup>2</sup>C compatible devices must recognize the stop condition. Upon the receipt of a stop condition, all devices know that the bus is released, and wait for a start condition followed by a matching address. If a transaction is terminated prematurely, the master needs to send a STOP condition to prevent the slave I<sup>2</sup>C logic from remaining in an incorrect state. Attempting to read data from register addresses not listed in this section will result in FFh being read out.



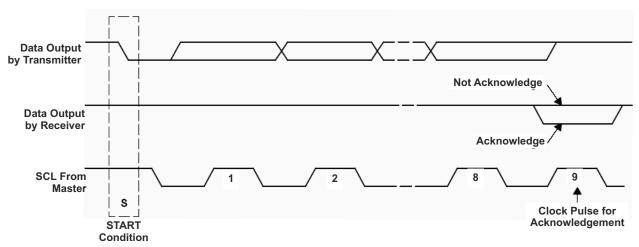


図 7-11. Acknowledge on the I<sup>2</sup>C Bus

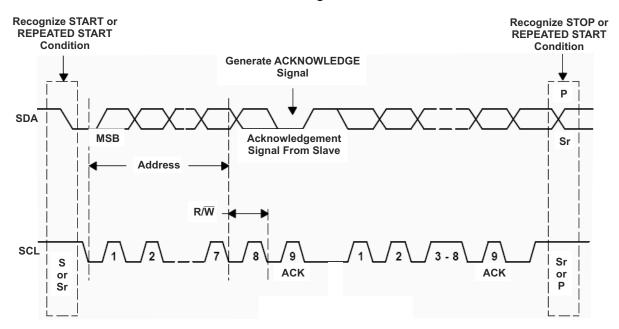


図 7-12. Bus Protocol



#### 7.4 Device Functional Modes

The BQ21061 has four main modes of operation: Active Battery Mode, Low Power Mode and Ship Mode which are battery only modes and Charge/Adapter Mode when a supply is connected to IN. 表 7-5 below summarizes the functions that are active for each operation mode. Each mode is discussed in further detail in the following sections in addition to the device's power-up/down sequences.

表 7-5. Function Availability Based on Primary Mode of Operation

| FUNCTION         | CHARGE/ ADAPTER<br>MODE | SHIP MODE | LOW POWER<br>MODE | ACTIVE BATTERY MODE |
|------------------|-------------------------|-----------|-------------------|---------------------|
| VOVP             | Yes                     | No        | Yes               | Yes                 |
| VUVLO            | Yes                     | Yes       | Yes               | Yes                 |
| BATOCP           | Yes                     | No        | No                | Yes                 |
| BATUVLO          | Yes                     | No        | Yes               | Yes                 |
| VINDPM           | If enabled              | No        | No                | No                  |
| DPPM             | If enabled              | No        | No                | No                  |
| VDD              | Yes                     | No        | Yes               | Yes                 |
| LS/LDO           | Yes                     | No        | If enabled        | If enabled          |
| BATFET           | Yes                     | No        | Yes               | Yes                 |
| TS Measurement   | Yes                     | No        | No                | If enabled          |
| Battery Changing | If enabled              | No        | No                | No                  |
| ILIM             | Yes (Register Value)    | No        | No                | No                  |
| MR input         | Yes                     | Yes       | Yes               | Yes                 |
| LP input         | No                      | No        | Yes               | Yes                 |
| ĪNT output       | Yes                     | No        | No                | Yes                 |
| I <sup>2</sup> C | Yes                     | No        | No                | Yes                 |
| CE input         | Yes                     | No        | No                | No                  |

#### 7.4.1 Ship Mode

Ship Mode is the lowest quiescent current state for the device. Ship Mode latches off the device and BAT FET until  $V_{IN} > V_{UVLO}$  or the  $\overline{MR}$  button is depressed for  $t_{WAKE1}$  and released. Ship mode can be entered regardless of the state of  $\overline{CE}$ . The device will also enter Ship Mode upon battery insertion when no valid VIN is present. If the EN\_SHIPMODE is written to a 1 while a valid input supply is connected, the device will wait until the IN supply is removed to enter ship mode. If the  $\overline{MR}$  pin is held low when the EN\_SHIPMODE bit is set, the device will wait until the  $\overline{MR}$  pin goes high before entering Ship Mode.  $\overline{\boxtimes}$  7-13 shows this behavior. The battery voltage must be above the maximum programmable  $V_{BATUVLO}$  threshold in order to exit Ship Mode with  $\overline{MR}$  press. The EN\_SHIPMODE bit can be cleared using the I²C interface while the VIN input is valid. The EN\_SHIPMODE bit is not cleared upon the I²C watchdog expiring, this means that if watchdog timer fault occurs while the EN\_SHIPMODE bit is set and the device is waiting to go into Ship Mode because  $V_{IN}$  is present or  $\overline{MR}$  is low, the device will still proceed to go into Ship Mode once those conditions are cleared.

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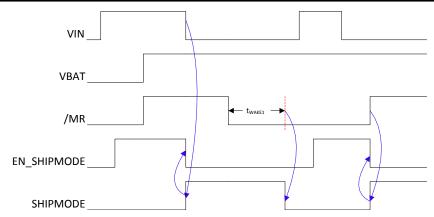


図 7-13. Ship Mode Entry Based On EN\_SHIPMODE bit

#### 7.4.2 Low Power

Low Power mode is a low quiescent current state while operating from the battery. The device will operate in low power mode when the  $\overline{LP}$  pin is set low,  $V_{IN} < V_{UVLO}$ ,  $\overline{MR}$  pin is high and all I²C transactions and interrupts that started while in the Active Battery or Charging Modes have been completed and sent. During LP mode the VDD output is powered by BAT, the  $\overline{MR}$  inputs are active and the I²C is disabled. All other circuits, such as oscillators, are in a low power or off state. The LS/LDO outputs will remain in the state set by the EN\_LS\_LDO bit prior to entering Low Power Mode. The device exits LP Mode when the  $\overline{LP}$  pin is set high or  $V_{IN} > V_{UVLO}$ .

In the case that a faulty adapter with  $V_{IN} > V_{OVP}$  is connected to the device while  $\overline{LP}$  pin is low, the device will be powered from the battery, but will operate in Active battery mode instead of Low Power mode regardless of the  $\overline{LP}$  pin state.

When  $\overline{MR}$  is held low while  $\overline{LP}$  is low, the device will enter Active Battery Mode, this allows for the internal clocks of the device to be running and allow the  $\overline{MR}$  long button press HW reset. I<sup>2</sup>C operation is also possible during this condition. Note that as soon as the  $\overline{MR}$  input is released and goes high, the device will go back to LP Mode tuning off all clocks. Note that if a HW reset has occurred while  $\overline{LP}$  is low,  $\overline{MR}$  must remain low until the power cycle has completed (PMID and LDO enable) to allow completion of the power up sequence.

## 7.4.3 Active Battery

If only battery is connected and the battery voltage goes below  $V_{BATUVLO}$ , the battery discharge FET is turned off. To provide designers the most flexibility in optimizing their system, an adjustable BATUVLO is provided. Deeper discharge of the battery enables longer times between charging, but may shorten the battery life. The BATUVLO is adjustable with a fixed 150-mV hysteresis.

#### 7.4.4 Charger/Adapter Mode

This mode is active when  $V_{\text{IN}} > V_{\text{UVLO}}$ . If the supply at IN is valid and above the  $V_{\text{IN\_DPM}}$  level, PMID will be powered by the supply connected to IN. The device will charge the battery, if charging is enabled, until termination has occurred.

#### 7.4.5 Power-Up/Down Sequencing

The power-up and power-down sequences for the BQ21061 are shown below. Upon  $V_{IN}$  insertion, VIN>  $V_{UVLO}$ , the device wakes up, powering the VDD rail. If  $V_{IN} > V_{BAT} + V_{SLP}$  and  $V_{IN} < V_{OVP}$ , PMID will be powered by VIN and if  $V_{IN} > V_{IN}$  ppm charging will start if enabled.

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In the case where  $V_{IN}$  <  $V_{UVLO}$  and the battery is inserted ( $V_{BAT}$  >  $V_{BATUVLO}$ ), the device will immediately enter Ship Mode unless  $\overline{MR}$  is held low. Upon battery insertion the VDD rail will come up to allow the device to check the  $\overline{MR}$  state and if  $\overline{MR}$  is high VDD will immediately be disabled and the device will enter Ship Mode. If  $\overline{MR}$  is low, the device will start the WAKE timer and power up PMID and other rails if  $\overline{MR}$  is held low for longer than  $t_{WAKE1}$ .

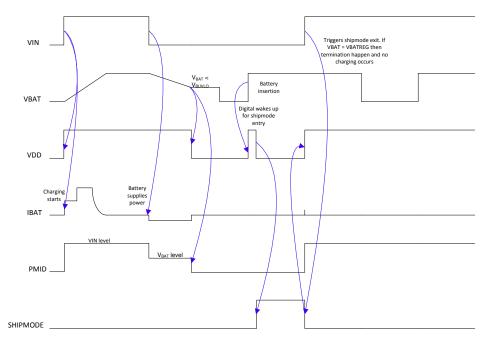


図 7-14. BQ21061 Wake-Up Upon Supply Insertion

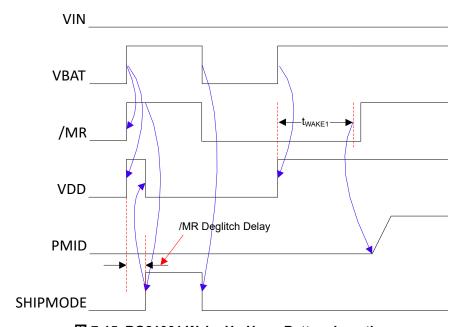


図 7-15. BQ21061 Wake-Up Upon Battery Insertion



# 7.5 Register Map

The device 7-bit address I<sup>2</sup>C is 0x6B (shifted 8-bit address is 0xD6).

## 7.5.1 I<sup>2</sup>C Registers

 $\frac{1}{2}$  7-6 lists the memory-mapped registers for the I<sup>2</sup>C registers. All register offset addresses not listed in  $\frac{1}{2}$  7-6 should be considered as reserved locations and the register contents should not be modified.

表 7-6. I<sup>2</sup>C Registers

| A al alasa a | A              | A 7-6. I-C Registers                   | 0 41    |
|--------------|----------------|--|---------|
| Address      | Acronym        | Register Name                          | Section |
| 0x0          | STAT0          | Charger Status 0                       | Go      |
| 0x1          | STAT1          | Charger Status 1                       | Go      |
| 0x2          | STAT2          | Status 2                               | Go      |
| 0x3          | FLAG0          | Charger Flags 0                        | Go      |
| 0x4          | FLAG1          | Charger Flags 1                        | Go      |
| 0x5          | FLAG2          | Flags 2                                | Go      |
| 0x6          | FLAG3          | Timer Flags                            | Go      |
| 0x7          | MASK0          | Interrupt Masks 0                      | Go      |
| 0x8          | MASK1          | Interrupt Masks 1                      | Go      |
| 0x9          | MASK2          | Interrupt Masks 2                      | Go      |
| 0xA          | MASK3          | Interrupt Masks 3                      | Go      |
| 0x12         | VBAT_CTRL      | Battery Voltage Control                | Go      |
| 0x13         | ICHG_CTRL      | Fast Charge Current Control            | Go      |
| 0x14         | PCHRGCTRL      | Pre-Charge Current Control             | Go      |
| 0x15         | TERMCTRL       | Termination Current Control            | Go      |
| 0x16         | BUVLO          | Battery UVLO and Current Limit Control | Go      |
| 0x17         | CHARGERCTRL0   | Charger Control 0                      | Go      |
| 0x18         | CHARGERCTRL1   | Charger Control 1                      | Go      |
| 0x19         | ILIMCTRL       | Input Current Limit Control            | Go      |
| 0x1D         | LDOCTRL        | LDO Control                            | Go      |
| 0x30         | MRCTRL         | MR Control                             | Go      |
| 0x35         | ICCTRL0        | IC Control 0                           | Go      |
| 0x36         | ICCTRL1        | IC Control 1                           | Go      |
| 0x37         | ICCTRL2        | IC Control 2                           | Go      |
| 0x61         | TS_FASTCHGCTRL | TS Charge Control                      | Go      |
| 0x62         | TS_COLD        | TS Cold Threshold                      | Go      |
| 0x63         | TS_COOL        | TS Cool Threshold                      | Go      |
| 0x64         | TS_WARM        | TS Warm Threshold                      | Go      |
| 0x65         | TS_HOT         | TS Hot Threshold                       | Go      |
| 0x6F         | DEVICE_ID      | Device ID                              | Go      |
|              |                |  |         |

Complex bit access types are encoded to fit into small table cells.  $\frac{1}{2}$  7-7 shows the codes that are used for access types in this section.

表 7-7. I<sup>2</sup>C Access Type Codes

| 20 0.100000      |        |                  |  |  |
|------------------|--------|------------------|--|--|
| Access Type Code |        | Description      |  |  |
| Read Type        |        |                  |  |  |
| R                | R      | Read             |  |  |
| RC               | C<br>R | to Clear<br>Read |  |  |

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表 7-7. I<sup>2</sup>C Access Type Codes (continued)

| Access Type Code |       | Description                            |  |  |  |  |
|------------------|-------|--|--|--|--|--|
| Write Type       |       |  |  |  |  |  |
| W                | W     | Write                                  |  |  |  |  |
| Reset or Default | Value |  |  |  |  |  |
| -n               |       | Value after reset or the default value |  |  |  |  |

# 7.5.1.1 STAT0 Register (Address = 0x0) [reset = X]

STAT0 is shown in  $ext{ <math> ext{ } e$ 

Return to Summary Table.

## 図 7-16. STAT0 Register

|          |                  |                      |                        | _                     |                        |                          |                    |
|----------|------------------|----------------------|------------------------|-----------------------|------------------------|--------------------------|--------------------|
| 7        | 6                | 5                    | 4                      | 3                     | 2                      | 1                        | 0                  |
| RESERVED | CHRG_CV_ST<br>AT | CHARGE_DON<br>E_STAT | IINLIM_ACTIVE<br>_STAT | VDPPM_ACTIV<br>E_STAT | VINDPM_ACTI<br>VE_STAT | THERMREG_A<br>CTIVE_STAT | VIN_PGOOD_S<br>TAT |
| R-X      | R-X              | R-X                  | R-X                    | R-X                   | R-X                    | R-X                      | R-X                |

表 7-8. STAT0 Register Field Descriptions

| Bit | Field                    | Туре | Reset | Description   |
|-----|--------------------------|------|-------|---|
| 7   | RESERVED                 | R    | X     | Reserved  |
| 6   | CHRG_CV_STAT             | R    | X     | Constant Voltage Charging Mode (Taper Mode) Status 1b0 = Not Active 1b1 = Active  |
| 5   | CHARGE_DONE_STAT         | R    | Х     | Charge Done Status 1b0 = Not Active 1b1 = Active  |
| 4   | IINLIM_ACTIVE_STAT       | R    | Х     | Input Current Limit Status 1b0 = Not Active 1b1 = Active  |
| 3   | VDPPM_ACTIVE_STAT        | R    | X     | DPPM Status 1b0 = Not Active 1b1 = Active   |
| 2   | VINDPM_ACTIVE_STAT       | R    | Х     | VINDPM Status 1b0 = Not Active 1b1 = Active   |
| 1   | THERMREG_ACTIVE_ST<br>AT | R    | Х     | Thermal Regulation Status 1b0 = Not Active 1b1 = Active   |
| 0   | VIN_PGOOD_STAT           | R    | Х     | VIN Power Good Status .  1b0 = Not Good  1b1 = V <sub>IN</sub> > V <sub>UVLO</sub> and V <sub>IN</sub> > V <sub>BAT</sub> + V <sub>SLP</sub> and V <sub>IN</sub> < V <sub>OVP</sub> |

## 7.5.1.2 STAT1 Register (Address = 0x1) [reset = X]

STAT1 is shown in 図 7-17 and described in 表 7-9.

Return to Summary Table.

## 図 7-17. STAT1 Register

| 7                      | 6        | 5                      | 4                       | 3                | 2                | 1                | 0           |
|------------------------|----------|------------------------|-------------------------|------------------|------------------|------------------|-------------|
| VIN_OVP_FAU<br>LT_STAT | RESERVED | BAT_OCP_FAU<br>LT_STAT | BAT_UVLO_FA<br>ULT_STAT | TS_COLD_STA<br>T | TS_COOL_STA<br>T | TS_WARM_ST<br>AT | TS_HOT_STAT |
| R-X                    | R-X      | R-X                    | R-X                     | R-X              | R-X              | R-X              | R-X         |

## 表 7-9. STAT1 Register Field Descriptions

| Bit | Field               | Туре | Reset | Description  |
|-----|---------------------|------|-------|--|
| 7   | VIN_OVP_FAULT_STAT  | R    | Х     | VIN Overvoltage Status 1b0 = Not Active 1b1 = Active   |
| 6   | RESERVED            | R    | Х     | Reserved   |
| 5   | BAT_OCP_FAULT_STAT  | R    | Х     | Battery Over-Current Protection Status  1b0 = Not Active  1b1 = Active   |
| 4   | BAT_UVLO_FAULT_STAT | R    | X     | Battery voltage below BATUVLO Level Status  1b0 = V <sub>BAT</sub> > V <sub>BATUVLO</sub> 1b1 = V <sub>BAT</sub> < V <sub>BATUVLO</sub>                          |
| 3   | TS_COLD_STAT        | R    | Х     | TS Cold Status - V <sub>TS</sub> > V <sub>COLD</sub> (charging suspended) 1b0 = Not Active 1b1 = Active  |
| 2   | TS_COOL_STAT        | R    | Х     | TS Cool Status - V <sub>COOL</sub> < V <sub>TS</sub> < V <sub>COLD</sub> (charging current reduced by value set by TS_Registers)  1b0 = Not Active  1b1 = Active |
| 1   | TS_WARM_STAT        | R    | Х     | TS Warm - V <sub>WARM</sub> > V <sub>TS</sub> >V <sub>HOT</sub> (charging voltage reduced by value set by TS_Registers) 1b0 = Not Active 1b1 = Active            |
| 0   | TS_HOT_STAT         | R    | X     | TS Hot Status - V <sub>TS</sub> < V <sub>HOT</sub> (charging suspended)<br>1b0 = Not Active<br>1b1 = Active  |

# 7.5.1.3 STAT2 Register (Address = 0x2) [reset = X]

STAT2 is shown in  $\boxtimes$  7-18 and described in  $\textcircled{\pi}$  7-10.

Return to Summary Table.

#### 図 7-18. STAT2 Register

| 7   | 6   | 5   | 4        | 3 | 2   | 1 | 0                |
|-----|-----|-----|----------|---|-----|---|------------------|
|     |     |     | RESERVED |   |     |   | TS_OPEN_STA<br>T |
| R-X | R-X | R-X | R-X      |   | R-X |   | R-X              |

## 表 7-10. STAT2 Register Field Descriptions

| Bit | Field    | Туре | Reset | Description |
|-----|----------|------|-------|-------------|
| 7-4 | RESERVED | R    | X     | Reserved    |

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表 7-10. STAT2 Register Field Descriptions (continued)

| Bit | Field        | Туре | Reset | Description  |
|-----|--------------|------|-------|--|
| 3-1 | RESERVED     | R    | Х     | Reserved   |
| 0   | TS_OPEN_STAT | R    |       | TS Open Status<br>1b0 = V <sub>TS</sub> < V <sub>OPEN</sub><br>1b1 = V <sub>TS</sub> > V <sub>OPEN</sub> |

# 7.5.1.4 FLAG0 Register (Address = 0x3) [reset = 0x0]

FLAG0 is shown in 図 7-19 and described in 表 7-11.

Return to Summary Table.

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## 図 7-19. FLAG0 Register

| 7        | 6                | 5                    | 4                      | 3                     | 2                      | 1                        | 0                  |
|----------|------------------|----------------------|------------------------|-----------------------|------------------------|--------------------------|--------------------|
| RESERVED | CHRG_CV_FL<br>AG | CHARGE_DON<br>E_FLAG | IINLIM_ACTIVE<br>_FLAG | VDPPM_ACTIV<br>E_FLAG | VINDPM_ACTI<br>VE_FLAG | THERMREG_A<br>CTIVE_FLAG | VIN_PGOOD_F<br>LAG |
| RC-1b0   | RC-1b0           | RC-1b0               | RC-1b0                 | RC-1b0                | RC-1b0                 | RC-1b0                   | RC-1b0             |

表 7-11. FLAG0 Register Field Descriptions

| Bit | Field                    | Туре                   | Reset     | Description  |
|-----|--------------------------|------------------------|-----------|--|
|     |                          |                        | 1 1 1 1 1 | •  |
| 7   | RESERVED                 | RC                     | 1b0       | Reserved   |
| 6   | CHRG_CV_FLAG             |                        |           | Constant Voltage Charging Mode (Taper Mode) Flag 1b0 = CV Mode Entry not detected 1b1 = CV Mode Entry detected   |
| 5   | CHARGE_DONE_FLAG         |                        |           | Charge Done Flag 1b0 = Charge Done (Termination) not detected 1b1 = Charge Done (Termination) detected   |
| 4   | IINLIM_ACTIVE_FLAG       | RC                     | 1b0       | Input Current Limit Flag 1b0 = Input Current Limit not detected 1b1 = Input Current Limit detected   |
| 3   | VDPPM_ACTIVE_FLAG        | PPM_ACTIVE_FLAG RC 1b0 |           | DPPM Flag 1b0 = DPPM operation not detected 1b1 = DPPM operation detected  |
| 2   | VINDPM_ACTIVE_FLAG       | RC                     | 1b0       | VINDPM Flag 1b0 = VINDPM operation not detected 1b1 = VIINDPM operation detected   |
| 1   | THERMREG_ACTIVE_FL<br>AG | RC                     | 1b0       | Thermal Regulation Flag 1b0 = Thermal Regulation not detected 1b1 = Thermal Regulation detected  |
| 0   | VIN_PGOOD_FLAG           | RC                     | 1b0       | VIN Power Good Flag . Interrupt will not be sent if device powers up with VIN_PGOOD condition and $V_{BAT} < V_{BATUVLO}$ 1b0 = No change in VIN Power Good Status 1b1 = Change in VIN Power Good Status detected. |

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# 7.5.1.5 FLAG1 Register (Address = 0x4) [reset = 0x0]

FLAG1 is shown in 図 7-20 and described in 表 7-12.

Return to Summary Table.



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## 図 7-20. FLAG1 Register

| 7                      | 6        | 5                      | 4                       | 3                | 2                | 1                | 0           |
|------------------------|----------|------------------------|-------------------------|------------------|------------------|------------------|-------------|
| VIN_OVP_FAU<br>LT_FLAG | RESERVED | BAT_OCP_FAU<br>LT_FLAG | BAT_UVLO_FA<br>ULT_FLAG | TS_COLD_FLA<br>G | TS_COOL_FLA<br>G | TS_WARM_FL<br>AG | TS_HOT_FLAG |
| RC-1b0                 | RC-1b0   | RC-1b0                 | RC-1b0                  | RC-1b0           | RC-1b0           | RC-1b0           | RC-1b0      |

表 7-12. FLAG1 Register Field Descriptions

| Bit | Field               | Туре | Reset | Description   |
|-----|---------------------|------|-------|---|
| 7   | VIN_OVP_FAULT_FLAG  | RC   | 1b0   | VIN Over Voltage Fault Flag 1b0 = No overvoltage condition detected 1b1 = VIN overvoltage condition detected                          |
| 6   | RESERVED            | RC   | 1b0   | Reserved  |
| 5   | BAT_OCP_FAULT_FLAG  | RC   | 1b0   | Battery Over Current Protection Flag  1b0 = No Battery Over Current condition detected  1b1 = Battery Over Current condition detected |
| 4   | BAT_UVLO_FAULT_FLAG | RC   | 1b0   | Battery Under Voltage Flag  1b0 = Battery below BATUVLO condition detected  1b1 = No Battery below BATUVLO condition detected         |
| 3   | TS_COLD_FLAG        | RC   | 1b0   | TS Cold Region Entry Flag  1b0 = TS Cold Region Entry not detected  1b1 = TS Cold Region Entry detected                               |
| 2   | TS_COOL_FLAG        | RC   | 1b0   | TS Cool Region Entry Flag 1b0 = TS Cool Region Entry not detected 1b1 = TS Co0l Region Entry detected                                 |
| 1   | TS_WARM_FLAG        | RC   | 1b0   | TS Warm Region Entry Flag 1b0 = TS Warm Region Entry not detected 1b1 = TS Warm Region Entry detected                                 |
| 0   | TS_HOT_FLAG         | RC   | 1b0   | TS Hot Region Entry Flag 1b0 = TS Hot Region Entry not detected 1b1 = TS Hot Region Entry detected                                    |

## 7.5.1.6 FLAG2 Register (Address = 0x5) [reset = 0x0]

FLAG2 is shown in 図 7-21 and described in 表 7-13.

Return to Summary Table.

Clear on Read

## 図 7-21. FLAG2 Register

| 7      | 6        | 5      | 4      | 3 | 2        | 1 | 0      |
|--------|----------|--------|--------|---|----------|---|--------|
|        | RESERVED |        |        |   |          |   |        |
| RC-1b0 | RC-1b0   | RC-1b0 | RC-1b0 |   | RC-3b000 |   | RC-1b0 |

# 表 7-13. FLAG2 Register Field Descriptions

|   | Bit | Field    | Туре | Reset | Description |
|---|-----|----------|------|-------|-------------|
| Ī | 7-4 | RESERVED | R    | X     | Reserved    |
| Ī | 3-1 | RESERVED | RC   | 3b000 | Reserved    |

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表 7-13. FLAG2 Register Field Descriptions (continued)

| Bit | Field        | Туре | Reset | Description   |
|-----|--------------|------|-------|---|
| 0   | TS_OPEN_FLAG | RC   |       | TS Open Flag 1b0 = No TS Open fault detected 1b1 = TS Open fault detected |

## 7.5.1.7 FLAG3 Register (Address = 0x6) [reset = 0x0]

FLAG3 is shown in 図 7-22 and described in 表 7-14.

Return to Summary Table.

Clear on Read

## 図 7-22. FLAG3 Register

| 7        | 6                 | 5                         | 4                      | 3        | 2                        | 1                        | 0                     |
|----------|-------------------|---------------------------|------------------------|----------|--------------------------|--------------------------|-----------------------|
| RESERVED | WD_FAULT_FL<br>AG | SAFETY_TMR_<br>FAULT_FLAG | LDO_OCP_FA<br>ULT_FLAG | RESERVED | MRWAKE1_TI<br>MEOUT_FLAG | MRWAKE2_TI<br>MEOUT_FLAG | MRRESET_WA<br>RN_FLAG |
| RC-1b0   | RC-1b0            | RC-1b0                    | RC-1b0                 | RC-1b0   | RC-1b0                   | RC-1b0                   | RC-1b0                |

## 表 7-14. FLAG3 Register Field Descriptions

|     | 20 1 11 1 2 100 1 10 glotor 1 10 10 2 000 1 ption 0 |      |       |  |  |  |  |  |
|-----|---|------|-------|--|--|--|--|--|
| Bit | Field   | Туре | Reset | Description  |  |  |  |  |
| 7   | RESERVED  | RC   | 1b0   | Reserved   |  |  |  |  |
| 6   | WD_FAULT_FLAG                                       | RC   | 1b0   | Watchdog Fault Flag  1b0 = Watchdog Timer not expired  1b1 = Watchdog Timer expired              |  |  |  |  |
| 5   | SAFETY_TMR_FAULT_F<br>LAG                           | RC   | 1b0   | Safety Timer Fault Flag  1b0 = Safety Timer not expired  1b1 = Safety Timer Expired              |  |  |  |  |
| 4   | LDO_OCP_FAULT_FLAG                                  | RC   | 1b0   | LDO Over Current Fault  1b0 = LDO Normal  1b1 = LDO Over current fault detected                  |  |  |  |  |
| 2   | MRWAKE1_TIMEOUT_FL<br>AG                            | RC   | 1b0   | MR Wake 1 Timer Flag  1b0 = MR Wake 1 timer not expired  1b1 = MR Wake 1 timer expired           |  |  |  |  |
| 1   | MRWAKE2_TIMEOUT_FL<br>AG                            | RC   | 1b0   | MR Wake 2 Timer Flag  1b0 = MR Wake 2 timer not expired  1b1 = MR Wake 2 timer expired           |  |  |  |  |
| 0   | MRRESET_WARN_FLAG                                   | RC   | 1b0   | MR Reset Warn Timer Flag 1b0 = MR Reset Warn timer not expired 1b1 = MR Reset Warn timer expired |  |  |  |  |

# 7.5.1.8 MASK0 Register (Address = 0x7) [reset = 0x0]

MASK0 is shown in  $\boxtimes$  7-23 and described in  $\not\equiv$  7-15.

Return to Summary Table.

#### 図 7-23. MASK0 Register

| 7        | 6                | 5                    | 4                      | 3                     | 2                      | 1                        | 0                  |
|----------|------------------|----------------------|------------------------|-----------------------|------------------------|--------------------------|--------------------|
| RESERVED | CHRG_CV_MA<br>SK | CHARGE_DON<br>E_MASK | IINLIM_ACTIVE<br>_MASK | VDPPM_ACTIV<br>E_MASK | VINDPM_ACTI<br>VE_MASK | THERMREG_A<br>CTIVE_MASK | VIN_PGOOD_<br>MASK |
| R/W-1b0  | R/W-1b0          | R/W-1b0              | R/W-1b0                | R/W-1b0               | R/W-1b0                | R/W-1b0                  | R/W-1b0            |



## 図 7-23. MASK0 Register (continued)

# 表 7-15. MASK0 Register Field Descriptions

| Bit | Field                    | Туре | Reset | Description  |
|-----|--------------------------|------|-------|--|
| 7   | RESERVED                 | R/W  | 1b0   | Reserved 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked                           |
| 6   | CHRG_CV_MASK             | R/W  | 1b0   | Mask for CHRG_CV interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked         |
| 5   | CHARGE_DONE_MASK         | R/W  | 1b0   | Mask for CHARGE_DONE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked     |
| 4   | IINLIM_ACTIVE_MASK       | R/W  | 1b0   | Mask for IINLIM_ACTIVE interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked |
| 3   | VDPPM_ACTIVE_MASK        | R/W  | 1b0   | Mask for VDPPM_ACTIVE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked    |
| 2   | VINDPM_ACTIVE_MASK       | R/W  | 1b0   | Mask for VINDPM_ACTIVE interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked |
| 1   | THERMREG_ACTIVE_M<br>ASK | R/W  | 1b0   | Mask for THERMREG_ACTIVE interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked |
| 0   | VIN_PGOOD_MASK           | R/W  | 1b0   | Mask for VIN_PGOOD interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked       |

# 7.5.1.9 MASK1 Register (Address = 0x8) [reset = 0x0]

MASK1 is shown in  $ext{ } ext{ }$ 

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## 図 7-24. MASK1 Register

| 7                      | 6        | 5                      | 4                       | 3                | 2                | 1                | 0               |
|------------------------|----------|------------------------|-------------------------|------------------|------------------|------------------|-----------------|
| VIN_OVP_FAU<br>LT_MASK | RESERVED | BAT_OCP_FAU<br>LT_MASK | BAT_UVLO_FA<br>ULT_MASK | TS_COLD_MA<br>SK | TS_COOL_MA<br>SK | TS_WARM_MA<br>SK | TS_HOT_MAS<br>K |
| R/W-1b0                | R/W-1b0  | R/W-1b0                | R/W-1b0                 | R/W-1b0          | R/W-1b0          | R/W-1b0          | R/W-1b0         |

# 表 7-16. MASK1 Register Field Descriptions

| Bit | Field              | Туре                   | Reset | Description  |
|-----|--------------------|------------------------|-------|--|
| 7   | VIN_OVP_FAULT_MASK | R/W                    | 1b0   | Mask for VIN_OVP_FAULT interrupt 1b0 = Interrupt Not Masked                        |
|     |                    |                        |       | 1b1 = Interrupt Masked   |
| 6   | RESERVED           | ERVED R/W 1b0 Reserved |       | Reserved   |
| 5   | BAT_OCP_FAULT_MASK | 1b0 = Interrupt Not    |       | Mask for BAT_OCP_FAULT interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked |

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表 7-16. MASK1 Register Field Descriptions (continued)

| Bit | Field              | Туре | Reset | Description   |
|-----|--------------------|------|-------|---|
| 4   | BAT_UVLO_FAULT_MAS | R/W  | 1b0   | Mask for BAT_UVLO_FAULT interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked |
| 3   | TS_COLD_MASK       | R/W  | 1b0   | Mask for TS_COLD interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked        |
| 2   | TS_COOL_MASK       | R/W  | 1b0   | Mask for TS_COOL interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked        |
| 1   | TS_WARM_MASK       | R/W  | 1b0   | Mask for TS_WARM interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked        |
| 0   | TS_HOT_MASK        | R/W  | 1b0   | Mask for TS_HOT interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked         |

# 7.5.1.10 MASK2 Register (Address = 0x9) [reset = 0x71]

MASK2 is shown in 図 7-25 and described in 表 7-17.

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## 図 7-25. MASK2 Register

| 7       | 6       | 5       | 4        | 3 | 2         | 1 | 0                |
|---------|---------|---------|----------|---|-----------|---|------------------|
|         |         |         | RESERVED |   |           |   | TS_OPEN_MA<br>SK |
| R/W-1b0 | R/W-1b1 | R/W-1b1 | R/W-1b1  |   | R/W-3b000 |   | R/W-1b1          |

## 表 7-17. MASK2 Register Field Descriptions

| Bit | Field        | Туре | Reset | Description  |
|-----|--------------|------|-------|--|
| 7   | RESERVED     | R    | Х     | Reserved   |
| 6   | RESERVED     | R    | Х     | Reserved   |
| 5   | RESERVED     | R    | Х     | Reserved   |
| 4   | RESERVED     | R    | Х     | Reserved   |
| 3-1 | RESERVED     | R/W  | 3b000 | Reserved   |
| 0   | TS_OPEN_MASK | R/W  | 1b1   | Mask for TS_OPEN Interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked |

# 7.5.1.11 MASK3 Register (Address = 0xA) [reset = 0x0]

MASK3 is shown in  $\boxtimes$  7-26 and described in  $\not\equiv$  7-18.

Return to Summary Table.

#### 図 7-26. MASK3 Register

| 7        | 6                 | 5                         | 4                      | 3        | 2                        | 1                        | 0                     |
|----------|-------------------|---------------------------|------------------------|----------|--------------------------|--------------------------|-----------------------|
| RESERVED | WD_FAULT_M<br>ASK | SAFETY_TMR_<br>FAULT_MASK | LDO_OCP_FA<br>ULT_MASK | RESERVED | MRWAKE1_TI<br>MEOUT_MASK | MRWAKE2_TI<br>MEOUT_MASK | MRRESET_WA<br>RN_MASK |
| R/W-1b0  | R/W-1b0           | R/W-1b0                   | R/W-1b0                | R/W-1b0  | R/W-1b0                  | R/W-1b0                  | R/W-1b0               |



#### 図 7-26. MASK3 Register (continued)

#### 表 7-18. MASK3 Register Field Descriptions

| Bit | Field                     | Туре | Reset | Description   |
|-----|---------------------------|------|-------|---|
| 7   | RESERVED                  | R/W  | 1b0   | Reserved  |
| 6   | WD_FAULT_MASK             | R/W  | 1b0   | Mask for WD_FAULT Interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked           |
| 5   | SAFETY_TMR_FAULT_M<br>ASK | R/W  | 1b0   | Mask for SAFETY_TIMER_FAULT Interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked |
| 4   | LDO_OCP_FAULT_MASK        | R/W  | 1b0   | Mask for LDO_OCP_FAULT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked        |
| 3   | RESERVED                  | R/W  | 1b0   | Reserved  |
| 2   | MRWAKE1_TIMEOUT_M<br>ASK  | R/W  | 1b0   | Mask for MRWAKE1_TIMEOUT Interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked    |
| 1   | MRWAKE2_TIMEOUT_M<br>ASK  | R/W  | 1b0   | Mask for MRWAKE2_TIMEOUT Interrupt 1b0 = Interrupt Not Masked 1b1 = Interrupt Masked      |
| 0   | MRRESET_WARN_MASK         | R/W  | 1b0   | Mask for MRRESET_WARN Interrupt  1b0 = Interrupt Not Masked  1b1 = Interrupt Masked       |

# 7.5.1.12 VBAT\_CTRL Register (Address = 0x12) [reset = 0x3C]

VBAT\_CTRL is shown in 図 7-27 and described in 表 7-19.

Return to Summary Table.

# 図 7-27. VBAT\_CTRL Register

| 7        | 6 | 5 | 4 | 3             | 2 | 1 | 0 |
|----------|---|---|---|---------------|---|---|---|
| RESERVED |   |   |   | VBAT_REG_6:0  |   |   |   |
| R/W-1b0  |   |   |   | R/W-7b0111100 |   |   |   |

## 表 7-19. VBAT\_CTRL Register Field Descriptions

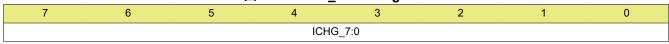
| Bit | Field        | Туре | Reset | Description   |
|-----|--------------|------|-------|---|
| 7   | RESERVED     | R/W  | 1b0   | Reserved  |
| 6-0 | VBAT_REG_6:0 | R/W  |       | Battery Regulation Voltage (4.2 V default)  VBATREG = 3.6 V + VBAT_REG code x 10 mV  If a value greater than 4.6 V is written, the setting will go to 4.6 V |

# 7.5.1.13 ICHG\_CTRL Register (Address = 0x13) [reset = 0x8]

ICHG\_CTRL is shown in 図 7-28 and described in 表 7-20.

Return to Summary Table.

#### 図 7-28. ICHG\_CTRL Register



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## 図 7-28. ICHG\_CTRL Register (continued)

R/W-8b00001000

#### 表 7-20. ICHG\_CTRL Register Field Descriptions

| Bi  | t | Field    | Туре | Reset      | Description  |
|-----|---|----------|------|------------|--|
| 7-0 | 0 | ICHG_7:0 | R/W  | 8b00001000 | Fast Charge Current (10 mA default)                        |
|     |   | _        |      |            | Fast Charge Current = 1.25 mA x ICHG code (ICHARGE_RANGE = |
|     |   |          |      |            | 0)   |
|     |   |          |      |            | Fast Charge Current = 2.5 mA x ICHG code (ICHARGE_RANGE =  |
|     |   |          |      |            | 1)   |

## 7.5.1.14 PCHRGCTRL Register (Address = 0x14) [reset = 0x2]

PCHRGCTRL is shown in 図 7-29 and described in 表 7-21.

Return to Summary Table.

## 図 7-29. PCHRGCTRL Register

|                   |      |       |   | - 3 |             |   |   |
|-------------------|------|-------|---|-----|-------------|---|---|
| 7                 | 6    | 5     | 4 | 3   | 2           | 1 | 0 |
| ICHARGE_RAN<br>GE | RESE | RVED  |   |     | IPRECHG_4:0 |   |   |
| R/W-1b0           | R/W  | -2b00 |   |     | R/W-5b00010 |   |   |

## 表 7-21. PCHRGCTRL Register Field Descriptions

| Bit | Field         | Туре | Reset   | Description  |
|-----|---------------|------|---------|--|
| 7   | ICHARGE_RANGE | R/W  | 1b0     | Charge Current Step  1b0 = 1.25 mA step (318.75 mA max charge current)  1b1 = 2.5 mA step (500 mA max charge current)  |
| 6-5 | RESERVED      | R/W  | 2b00    | Reserved   |
| 4-0 | IPRECHG_4:0   | R/W  | 5b00010 | Pre-Charge Current (2.5 mA default) Pre-Charge Current = 1.25 mA x IPRECHG code (ICHARGE_RANGE = 0) Pre-Charge Current = 2.5 mA x IPRECHG code (ICHARGE_RANGE = 1) |

## 7.5.1.15 TERMCTRL Register (Address = 0x15) [reset = 0x14]

TERMCTRL is shown in 図 7-30 and described in 表 7-22.

Return to Summary Table.

#### 図 7-30. TERMCTRL Register

| 7    | 6     | 5 | 4 | 3           | 2 | 1 | 0                |
|------|-------|---|---|-------------|---|---|------------------|
| RESE | RVED  |   |   | ITERM_4:0   |   |   | TERM_DISABL<br>E |
| R/W  | -2b00 |   |   | R/W-5b01010 |   |   | R/W-1b0          |

#### 表 7-22. TERMCTRL Register Field Descriptions

| Bit | Field    | Туре | Reset | Description |
|-----|----------|------|-------|-------------|
| 7-6 | RESERVED | R/W  | 2b00  | Reserved    |



# 表 7-22. TERMCTRL Register Field Descriptions (continued)

| Bit | Field        | Туре | Reset   | Description  |
|-----|--------------|------|---------|--|
| 5-1 | ITERM_4:0    | R/W  | 5b01010 | Termination Current (10% of ICHRG default) Programmable Range = 1% to 31% of ICHRG 5b00000 = Do not Use 5b00001 = 1% of ICHRG 5b00010 = 2% of ICHRG 5b00100 = 4% of ICHRG 5b01000 = 8% of ICHRG 5b10000 = 16% of ICHRG |
| 0   | TERM_DISABLE | R/W  | 1b0     | Termination Disable  1b0 = Termination Enabled  1b1 = Termination Disabled   |

## 7.5.1.16 BUVLO Register (Address = 0x16) [reset = 0x0]

BUVLO is shown in 図 7-31 and described in 表 7-23.

Return to Summary Table.

# 図 7-31. BUVLO Register

| 7        | 6 | 5         | 4        | 3          | 2 | 1         | 0 |
|----------|---|-----------|----------|------------|---|-----------|---|
| RESERVED |   | VLOWV_SEL | IBAT_OCF | P_ILIM_1:0 |   | BUVLO_2:0 |   |
| R/W-2b00 |   | R/W-1b0   | R/W-     | -2b00      |   | R/W-3b000 |   |

#### 表 7-23. BUVLO Register Field Descriptions

| Bit | Field             | Туре | Reset   | Description   |
|-----|-------------------|------|---|---|
| 7-6 | RESERVED          | R/W  | 2b00  | Reserved  |
| 5   | VLOWV_SEL         | R/W  | 1b0   | Pre-charge to Fast Charge Threshold<br>1b0 = 3.0 V<br>1b1 = 2.8 V |
| 4-3 | IBAT_OCP_ILIM_1:0 |      | 2b00 = 1200 mA<br>2b01 = 1500 mA<br>2b10 = Disabled |   |
| 2-0 | BUVLO_2:0         | R/W  | 3b000   | 3b000 = 3.0 V   |

Product Folder Links: BQ21061

# 7.5.1.17 CHARGERCTRL0 Register (Address = 0x17) [reset = 0x82]

CHARGERCTRL0 is shown in 図 7-32 and described in 表 7-24.

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#### 図 7-32. CHARGERCTRL0 Register

| 7       | 6                   | 5          | 4                    | 3        | 2           | 1           | 0        |
|---------|---------------------|------------|----------------------|----------|-------------|-------------|----------|
| TS_EN   | TS_CONTROL<br>_MODE | VRH_THRESH | WATCHDOG_D<br>ISABLE | 2XTMR_EN | SAFETY_TIME | R_LIMIT_1:0 | RESERVED |
| R/W-1b1 | R/W-1b0             | R/W-1b0    | R/W-1b0              | R/W-1b0  | R/W-2       | 2b01        | R/W-1b0  |

## 表 7-24. CHARGERCTRL0 Register Field Descriptions

| Bit | Field                  | Туре  | Reset | Description   |
|-----|------------------------|---|-------|---|
| 7   | TS_EN                  | R/W   | 1b1   | TS Function Enable 1b0 = TS function disabled (Only charge control is disabled. TS_OPEN detection and TS ADC monitoring remain enabled) 1b1 = TS function enabled |
| 6   | TS_CONTROL_MODE        | 1b0 = Custom (JEITA) 1b1 = Disable charging on HOT/COLD Only  R/W 1b0 Recharge Voltage Threshold 1b0 = 140 mV |       | 1b0 = Custom (JEITA)  |
| 5   | VRH_THRESH             | 1b0 = 140 mV<br>1b1 = 200 mV  |       | 1b0 = 140 mV  |
| 4   | WATCHDOG_DISABLE       | R/W   | 1b0   | Watchdog Timer Disable 1b0 = Watchdog timer enabled 1b1 = Watchdog timer disabled   |
| 3   | 2XTMR_EN               | R/W   | 1b0   | Enable 2X Safety Timer  1b0 = The timer is not slowed at any time  1b1 = The timer is slowed by 2x when in any control other than CC or CV                        |
| 2-1 | SAFETY_TIMER_LIMIT_1:0 | R/W   | 2b01  | Charger Safety Timer 2b00 = 3 Hr Fast Charge 2b01 = 6 Hr Fast Charge 2b10 = 12 Hr Fast Charge 2b11 = Disabled   |
| 0   | RESERVED               | R/W   | 1b0   | Reserved  |

# 7.5.1.18 CHARGERCTRL1 Register (Address = 0x18) [reset = 0xC2]

CHARGERCTRL1 is shown in 図 7-33 and described in 表 7-25.

Return to Summary Table.

## 図 7-33. CHARGERCTRL1 Register

| 7          | 6 | 5          | 4 | 3        | 2             | 1         | 0 |  |
|------------|---|------------|---|----------|---------------|-----------|---|--|
| VINDPM_DIS |   | VINPDM_2:0 |   | DPPM_DIS | THERM_REG_2:0 |           |   |  |
| R/W-1b1    |   | R/W-3b100  |   | R/W-1b0  |               | R/W-3b010 |   |  |

## 表 7-25. CHARGERCTRL1 Register Field Descriptions

| Bit | Field | d       | Type Reset |     | Description  |  |  |
|-----|-------|---------|------------|-----|--|--|--|
| 7   | VINI  | DPM_DIS | R/W        | 1b1 | Disable VINDPM Function  1b0 = VINDPM Enabled  1b1 = VINDPM Disabled |  |  |



# 表 7-25. CHARGERCTRL1 Register Field Descriptions (continued)

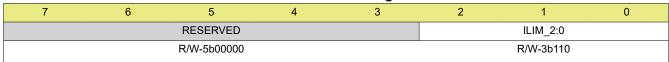
| Bit | Field         | Туре | Reset | Description  |
|-----|---------------|------|-------|--|
| 6-4 | VINPDM_2:0    | R/W  | 3b100 | VINDPM Level Selection<br>3b000 = 4.2 V<br>3b001 = 4.3 V<br>3b010 = 4.4 V<br>3b011 = 4.5 V<br>3b100 = 4.6 V<br>3b101 = 4.7 V<br>3b110 = 4.8 V            |
| 3   | DPPM_DIS      | R/W  | 1b0   | 3b111 = 4.9 V  DPPM Disable  1b0 = DPPM function enabled  1b1 = DPPM function disabled   |
| 2-0 | THERM_REG_2:0 | R/W  | 3b010 | Thermal Charge Current Foldback Threshold 3b000 = 80°C 3b001 = 85°C 3b010 = 90°C 3b011 = 95°C 3b100 = 100°C 3b101 = 105°C 3b110 = 110°C 3b111 = Disabled |

# 7.5.1.19 ILIMCTRL Register (Address = 0x19) [reset = 0x6]

ILIMCTRL is shown in 図 7-34 and described in 表 7-26.

Return to Summary Table.

#### 図 7-34. ILIMCTRL Register



# 表 7-26. ILIMCTRL Register Field Descriptions

| Bit | Field    | Туре | Reset   | Description  |
|-----|----------|------|---------|--|
| 7-3 | RESERVED | R/W  | 5b00000 | Reserved   |
| 2-0 | ILIM_2:0 | R/W  | 3b110   | Input Current Limit Level Selection<br>3b000 = 50 mA<br>3b001 = 100 mA<br>3b010 = 150 mA |
|     |          |      |         | 3b011 = 200 mA<br>3b100 = 300 mA<br>3b101 = 400 mA<br>3b110 = 500 mA<br>3b111 = 600 mA   |

## 7.5.1.20 LDOCTRL Register (Address = 0x1D) [reset = 0xB0]

LDOCTRL is shown in 図 7-35 and described in 表 7-27.

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## 図 7-35. LDOCTRL Register

| 7         | 6 | 5 | 4           | 3 | 2 | 1                    | 0        |
|-----------|---|---|-------------|---|---|----------------------|----------|
| EN_LS_LDO |   |   | VLDO_4:0    |   |   | LDO_SWITCH_<br>CONFG | RESERVED |
| R/W-1b1   |   |   | R/W-5b01100 |   |   | R/W-1b0              | R/W-1b0  |

表 7-27. LDOCTRL Register Field Descriptions

| Bit | Field            | Туре    | Reset   | Description  |  |  |
|-----|------------------|---------|---------|--|--|--|
| 7   | EN_LS_LDO        | R/W 1b1 |         | LS/LDO Enable  1b0 = Disable LS/LDO  1b1 = Enable LS/LDO                             |  |  |
| 6-2 | VLDO_4:0         | R/W     | 5b01100 | LDO output voltage setting (1.8 V default) LDO Voltage = 600 mV + VLDO Code x 100 mV |  |  |
| 1   | LDO_SWITCH_CONFG | R/W     | 1b0     | LDO / Load Switch Configuration Select 1b0 = LDO 1b1 = Load Switch                   |  |  |
| 0   | RESERVED         | R/W     | 1b0     | Reserved   |  |  |

# 7.5.1.21 MRCTRL Register (Address = 0x30) [reset = 0x2A]

MRCTRL is shown in 🗵 7-36 and described in 表 7-28.

Return to Summary Table.

## 図 7-36. MRCTRL Register

| 7                | 6                  | 5                  | 4         | 3         | 2       | 1        | 0        |
|------------------|--------------------|--------------------|-----------|-----------|---------|----------|----------|
| MR_RESET_VI<br>N | MR_WAKE1_TI<br>MER | MR_WAKE2_TI<br>MER | MR_RESET_ | _WARN_1:0 | MR_HW_R | ESET_1:0 | RESERVED |
| R/W-1b0          | R/W-1b0            | R/W-1b1            | R/W-      | 2b01      | R/W-2   | 2b01     | R/W-1b0  |

## 表 7-28. MRCTRL Register Field Descriptions

| Bit | Field             | Туре | Reset | Description   |
|-----|-------------------|------|-------|---|
| 7   | MR_RESET_VIN      | R/W  | 1b0   | VIN Power Good gated MR Reset Enable 1b0 = Reset sent when /MR reset time is met regardless of VIN state 1b1 = Reset sent when MR reset is met and Vin is valid |
| 6   | MR_WAKE1_TIMER    | R/W  | 1b0   | Wake 1 Timer setting 1b0 = 125 ms 1b1 = 500 ms  |
| 5   | MR_WAKE2_TIMER    | R/W  | 1b1   | Wake 2 Timer setting 1b0 = 1 s 1b1 = 2 s  |
| 4-3 | MR_RESET_WARN_1:0 | R/W  | 2b01  | MR Reset Warn Timer setting 2b00 = MR_HW_RESET - 0.5 s 2b01 = MR_HW_RESET - 1.0 s 2b10 = MR_HW_RESET - 1.5 s 2b11 = MR_HW_RESET - 2.0 s                         |
| 2-1 | MR_HW_RESET_1:0   | R/W  | 2b01  | MR HW Reset Timer setting 2b00 = 4 s 2b01 = 8 s 2b10 = 10 s 2b11 = 14 s   |



表 7-28. MRCTRL Register Field Descriptions (continued)

| Bit | Field    | Туре | Reset | Description |
|-----|----------|------|-------|-------------|
| 0   | RESERVED | R/W  | 1b0   | Reserved    |

# 7.5.1.22 ICCTRL0 Register (Address = 0x35) [reset = 0x10]

ICCTRL0 is shown in 図 7-37 and described in 表 7-29.

Return to Summary Table.

# 図 7-37. ICCTRL0 Register

| 7                | 6        | 5      | 4      | 3        | 2                   | 1        | 0        |
|------------------|----------|--------|--------|----------|---------------------|----------|----------|
| EN_SHIP_MOD<br>E | RESERVED | AUTOWA | KE_1:0 | RESERVED | GLOBAL_INT_<br>MASK | HW_RESET | SW_RESET |
| R/W-1b0          | R/W-1b0  | R/W-2  | b01    | R/W-1b0  | R/W-1b0             | R/W-1b0  | R/W-1b0  |

#### 表 7-29. ICCTRL0 Register Field Descriptions

|     |                 | 3X / 20. I | OO II KEO IK | sgister riela bescriptions   |
|-----|-----------------|------------|--------------|--|
| Bit | Field           | Type       | Reset        | Description  |
| 7   | EN_SHIP_MODE    | R/W        | 1b0          | Ship Mode Enable 1b0 = Normal operation 1b1 = Enter Ship Mode when VIN is not valid and /MR is high  |
| 6   | RESERVED        | R/W        | 1b0          | Reserved   |
| 5-4 | AUTOWAKE_1:0    | R/W        | 2b01         | Auto-wakeup Timer (TRESTART) for /MR HW Reset<br>2b00 = 0.6 s<br>2b01 = 1.2 s<br>2b10 = 2.4 s<br>2b11 = 5 s  |
| 3   | RESERVED        | R/W        | 1b0          | Reserved   |
| 2   | GLOBAL_INT_MASK | R/W        | 1b0          | Global Interrupt Mask 1b0 = Normal Operation 1b1 = Mask all interrupts   |
| 1   | HW_RESET        | R/W        | 1b0          | HW Reset  1b0 = Normal operation  1b1 = HW Reset. Temporarily power down all power rails, except  VDD. I <sup>2</sup> C Register go to default settings. |
| 0   | SW_RESET        | R/W        | 1b0          | SW_Reset  1b0 = Normal operation  1b1 = SW Reset. I <sup>2</sup> C Registers go to default settings.   |

## 7.5.1.23 ICCTRL1 Register (Address = 0x36) [reset = 0x0]

ICCTRL1 is shown in 図 7-38 and described in 表 7-30.

Return to Summary Table.

#### 図 7-38. ICCTRL1 Register

| 7                    | 6 | 5        | 4        | 3     | 2       | 1      | 0       |
|----------------------|---|----------|----------|-------|---------|--------|---------|
| MR_LPRESS_ACTION_1:0 |   | RESERVED | RESERVED | PG_MC | DDE_1:0 | PMID_M | ODE_1:0 |
| R/W-2b00             |   | R/W-1b0  | R/W-1b0  | R/W-  | -2b00   | R/W-   | 2b00    |

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# 表 7-30. ICCTRL1 Register Field Descriptions

|     | A 1-50. TO TILLI Register Field Descriptions |      |       |   |  |  |  |  |  |  |
|-----|--|------|-------|---|--|--|--|--|--|--|
| Bit | Field  | Туре | Reset | Description   |  |  |  |  |  |  |
| 7-6 | MR_LPRESS_ACTION_1:<br>0                     | R/W  | 2b00  | MR Long Press Action 2b00 = HW Reset (Power Cycle) 2b01 = Do nothing 2b10 = Enter Ship Mode 2b11 = Enter Ship Mode  |  |  |  |  |  |  |
| 5   | RESERVED                                     | R/W  | 1b0   | Reserved  |  |  |  |  |  |  |
| 4   | RESERVED                                     | R/W  | 1b0   | Reserved  |  |  |  |  |  |  |
| 3-2 | PG_MODE_1:0                                  | R/W  | 2b00  | $\overrightarrow{PG}$ Pin Mode of Operation 2b00 = VIN Power Good. $\overrightarrow{PG}$ pulls to GND when $V_{IN} > V_{UVLO}, V_{IN} > V_{BAT} + V_{SLP}$ and $V_{IN} < V_{IN\_OVP}.$ 2b01 = Deglitched Level Shifted /MR. $\overrightarrow{PG}$ is high impedance when the $\overrightarrow{MR}$ input is high, and $\overrightarrow{PG}$ pulls to GND when the $\overrightarrow{MR}$ input is low. 2b1x = General Purpose Open Drain Output. The state of the $\overrightarrow{PG}$ pin is then controlled through the GPO_PG bit, where if GPO_PG is 0 , the $\overrightarrow{PG}$ pin is pulled to GND and if it is 1, the $\overrightarrow{PG}$ pin is in high impedance. |  |  |  |  |  |  |
| 1-0 | PMID_MODE_1:0                                | R/W  | 2b00  | PMID Control Sets how PMID is powered in any state, except Ship Mode. 2b00 = PMID powered from BAT or VIN if present 2b01 = PMID powered from BAT only, even if VIN is present 2b10 = PMID disconnected and left floating 2b11 = PMID disconnected and pulled down.   |  |  |  |  |  |  |

# 7.5.1.24 ICCTRL2 Register (Address = 0x37) [reset = 0x40]

ICCTRL2 is shown in 図 7-39 and described in 表 7-31.

Return to Summary Table.

## 図 7-39. ICCTRL2 Register

| 7                 | 6         | 5      | 4       | 3     | 2                  | 1                   | 0       |
|-------------------|-----------|--------|---------|-------|--------------------|---------------------|---------|
| PMID_REG_CTRL_2:0 |           | GPO_PG | RESE    | RVED  | HWRESET_14<br>S_WD | CHARGER_DIS<br>ABLE |         |
|                   | R/W-3b010 |        | R/W-1b0 | R/W-2 | 2b00               | R/W-1b0             | R/W-1b0 |

# 表 7-31. ICCTRL2 Register Field Descriptions

| Bit | Field             | Туре | Reset | Description                              |
|-----|-------------------|------|-------|--|
| 7-5 | PMID_REG_CTRL_2:0 | R/W  | 3b010 | System (PMID) Regulation Voltage         |
|     |                   |      |       | 3b000 = Battery Tracking                 |
|     |                   |      |       | 3b001 = 4.4 V                            |
|     |                   |      |       | 3b010 = 4.5 V                            |
|     |                   |      |       | 3b011 = 4.6 V                            |
|     |                   |      |       | 3b100 = 4.7 V                            |
|     |                   |      |       | 3b101 = 4.8 V                            |
|     |                   |      |       | 3b110 = 4.9 V                            |
|     |                   |      |       | 3b111 = Pass-Through (V <sub>IN</sub> )  |
| 4   | GPO_PG            | R/W  | 1b0   | /PG General Purpose Output State Control |
|     |                   |      |       | 1b0 = Pulled Down                        |
|     |                   |      |       | 1b1 = High Z                             |
| 3-2 | RESERVED          | R/W  | 2b00  | Reserved                                 |



表 7-31. ICCTRL2 Register Field Descriptions (continued)

| Bit | Field           | Туре | Reset | Description  |
|-----|-----------------|------|-------|--|
| 1   | HWRESET_14S_WD  | R/W  | 1b0   | Enable for 14-second I <sup>2</sup> C watchdog timer for HW Reset after VIN connection 1b0 = Timer disabled 1b1 = Device will perform HW reset if no I <sup>2</sup> C transaction is done within 14 s after VIN is present |
| 0   | CHARGER_DISABLE | R/W  | 1b0   | Charge Disable  1b0 = Charge enabled if /CE pin is low  1b1 = Charge disabled  |

## 7.5.1.25 TS\_FASTCHGCTRL Register (Address = 0x61) [reset = 0x34]

TS\_FASTCHGCTRL is shown in 図 7-40 and described in 表 7-32.

Return to Summary Table.

#### 図 7-40. TS\_FASTCHGCTRL Register

|          |    |               | _ |          |   |              |   |
|----------|----|---------------|---|----------|---|--------------|---|
| 7        | 6  | 5             | 4 | 3        | 2 | 1            | 0 |
| RESERVED | T: | S_VBAT_REG2:0 | 0 | RESERVED |   | TS_ICHRG_2:0 |   |
| R/W-1b0  |    | R/W-3b011     |   | R/W-1b0  |   | R/W-3b100    |   |

#### 表 7-32. TS FASTCHGCTRL Register Field Descriptions

| Bit | Field          | Type | Reset | Description  |
|-----|----------------|------|-------|--|
| 7   | RESERVED       | R/W  | 1b0   | Reserved   |
| 6-4 | TS_VBAT_REG2:0 | R/W  | 3b011 | Reduced target battery voltage during Warm  3b000 = No reduction  3b001 = VBAT_REG - 50 mV  3b010 = VBAT_REG - 100 mV  3b011 = VBAT_REG - 150 mV  3b100 = VBAT_REG - 200 mV  3b101 = VBAT_REG - 250 mV  3b110 = VBAT_REG - 300 mV  3b111 = VBAT_REG - 350 mV |
| 3   | RESERVED       | R/W  | 1b0   | Reserved   |
| 2-0 | TS_ICHRG_2:0   | R/W  | 3b100 | Fast charge current when decreased by TS function  3b000 = No reduction  3b001 = 0.875 x ICHG  3b010 = 0.750 x ICHG  3b011 = 0.625 x ICHG  3b100 = 0.500 x ICHG  3b101 = 0.375 x ICHG  3b110 = 0.250 x ICHG  3b111 = 0.125 x ICHG                            |

## 7.5.1.26 TS\_COLD Register (Address = 0x62) [reset = 0x7C]

TS\_COLD is shown in 図 7-41 and described in 表 7-33.

Return to Summary Table.

## 図 7-41. TS\_COLD Register

|   |   |   | _ | • |   |   |   |
|---|---|---|---|---|---|---|---|
| 7 | 6 | 5 | 4 | 3 | 2 | 1 | 0 |

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## 図 7-41. TS\_COLD Register (continued)

TS\_COLD\_7:0

R/W-8b01111100

表 7-33. TS\_COLD Register Field Descriptions

| Bit | Field       | Туре | Reset      | Description        |
|-----|-------------|------|------------|--------------------|
| 7-0 | TS_COLD_7:0 | R/W  | 8b01111100 | TS Cold Threshold  |
|     |             |      |            | 1b = 4.688 mV      |
|     |             |      |            | 10b = 9.375 mV     |
|     |             |      |            | 100b = 18.75 mV    |
|     |             |      |            | 1000b = 37.5 mV    |
|     |             |      |            | 10000b = 75 mV     |
|     |             |      |            | 100000b = 150 mV   |
|     |             |      |            | 1000000b = 300 mV  |
|     |             |      |            | 10000000b = 600 mV |

## 7.5.1.27 TS\_COOL Register (Address = 0x63) [reset = 0x6D]

TS\_COOL is shown in  $\boxtimes$  7-42 and described in 表 7-34.

Return to Summary Table.

## 図 7-42. TS\_COOL Register

| 7 | 6 | 5 | 4       | 3        | 2 | 1 | 0 |
|---|---|---|---------|----------|---|---|---|
|   |   |   | TS_CO   | OL_7:0   |   |   |   |
|   |   |   | R/W-8b0 | )1101101 |   |   |   |

## 表 7-34. TS\_COOL Register Field Descriptions

| Bit | Field       | Туре | Reset      | Description        |
|-----|-------------|------|------------|--------------------|
| 7-0 | TS_COOL_7:0 | R/W  | 8b01101101 | TS Cool Threshold  |
|     |             |      |            | 1b = 4.688 mV      |
|     |             |      |            | 10b = 9.375 mV     |
|     |             |      |            | 100b = 18.75 mV    |
|     |             |      |            | 1000b = 37.5 mV    |
|     |             |      |            | 10000b = 75 mV     |
|     |             |      |            | 100000b = 150 mV   |
|     |             |      |            | 1000000b = 300 mV  |
|     |             |      |            | 10000000b = 600 mV |

# 7.5.1.28 TS\_WARM Register (Address = 0x64) [reset = 0x38]

TS\_WARM is shown in 図 7-43 and described in 表 7-35.

Return to Summary Table.

# 図 7-43. TS\_WARM Register

| 7 | 6 | 5 | 4       | 3       | 2 | 1 | 0 |
|---|---|---|---------|---------|---|---|---|
|   |   |   | TS_WA   | RM_7:0  |   |   |   |
|   |   |   | R/W-8b0 | 0111000 |   |   |   |



表 7-35. TS\_WARM Register Field Descriptions

| Field       | Туре | Reset      | Description        |
|-------------|------|------------|--------------------|
| TS_WARM_7:0 | R/W  | 8b00111000 | TS Warm Threshold  |
|             |      |            | 1b = 4.688 mV      |
|             |      |            | 10b = 9.375 mV     |
|             |      |            | 100b = 18.75 mV    |
|             |      |            | 1000b = 37.5 mV    |
|             |      |            | 10000b = 75 mV     |
|             |      |            | 100000b = 150 mV   |
|             |      |            | 1000000b = 300 mV  |
|             |      |            | 10000000b = 600 mV |
|             |      | 7,1        | 71                 |

## 7.5.1.29 TS\_HOT Register (Address = 0x65) [reset = 0x27]

TS\_HOT is shown in 図 7-44 and described in 表 7-36.

Return to Summary Table.

## 図 7-44. TS\_HOT Register



## 表 7-36. TS\_HOT Register Field Descriptions

|     | Bit | Field      | Туре | Reset      | Description        |
|-----|-----|------------|------|------------|--------------------|
| ſ   | 7-0 | TS_HOT_7:0 | R/W  | 8b00100111 | TS Hot Threshold   |
|     |     |            |      |            | 1b = 4.688 mV      |
|     |     |            |      |            | 10b = 9.375 mV     |
|     |     |            |      |            | 100b = 18.75 mV    |
|     |     |            |      |            | 1000b = 37.5 mV    |
|     |     |            |      |            | 10000b = 75 mV     |
|     |     |            |      |            | 100000b = 150 mV   |
|     |     |            |      |            | 1000000b = 300 mV  |
|     |     |            |      |            | 10000000b = 600 mV |
| - 1 |     | I .        | 1    | 1          |                    |

## 7.5.1.30 DEVICE\_ID Register (Address = 0x6F) [reset = 0x3A]

DEVICE\_ID is shown in  $\boxtimes$  7-45 and described in \$ 7-37.

Return to Summary Table.

## 図 7-45. DEVICE\_ID Register

| 7 | 6 | 5 | 4      | 3       | 2 | 1 | 0 |
|---|---|---|--------|---------|---|---|---|
|   |   |   | DEVICE | _ID_7:0 |   |   |   |
|   |   |   | R-8b00 | )111010 |   |   |   |

## 表 7-37. DEVICE\_ID Register Field Descriptions

| Bit | Field Type Re |   | Reset | Description         |
|-----|---------------|---|-------|---------------------|
| 7-0 | DEVICE_ID_7:0 | R |       |                     |
|     |               |   |       | 00111010b = BQ21061 |

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# 8 Application and Implementation

注

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#### 8.1 Application Information

A typical application of the BQ21061 consists of the device configured as an I<sup>2</sup>C controlled single cell Li-ion battery charger and power path manager or small battery applications such as smart-watches and wireless headsets. A battery thermistor may be connected to the TS pin to allow the device to monitor the battery temperature and control charging as desired.

The system designer may connect the  $\overline{\text{MR}}$  input to a push-button to send interrupts to the host as the button is pressed or to allow the application's end user to reset the system. If not used this pin must be left floating or tied to BAT.

## 8.2 Typical Application

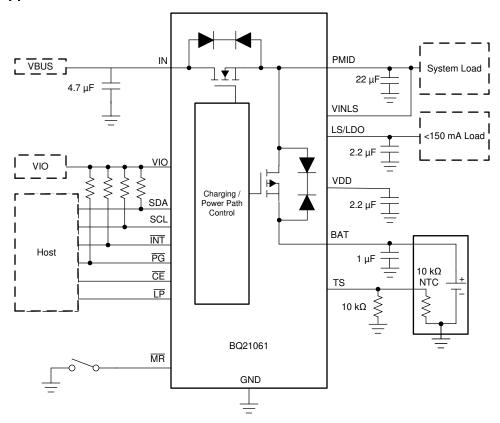


図 8-1. Typical Application Diagram



#### 8.2.1 Design Requirements

The design parameters for the following design example are shown in 表 8-1 below.

表 8-1. Design Parameters

| PARAMETER                  | VALUE       |
|----------------------------|-------------|
| IN Supply Voltage          | 5 V         |
| Battery Regulation Voltage | 4.2 V       |
| LDO Output Voltage         | LDO (1.8 V) |

#### 8.2.2 Detailed Design Procedure

#### 8.2.2.1 Input (IN/PMID) Capacitors

Low ESR ceramic capacitors such as X7R or X5R is preferred for input decoupling capacitors and should be places as close as possible to the supply and ground pins fo the IC. Due to the voltage derating of the capacitors it is recommended at 25-V rated capacitors are used for IN and PMID pins which can normally operate at 5 V. After derating the minimum capacitance must be higher than 1  $\mu$ F.

#### 8.2.2.2 VDD, LDO Input and Output Capacitors

A Low ESR ceramic capacitor such as X7R or X5R is recommended for the LDO decoupling capacitor. A 4.7- $\mu$ F capacitor is recommended for VDD output. For the LDO output a 2.2- $\mu$ F capacitor is recommended. The minimum supported capacitance after derating must be higher than 1  $\mu$ F to ensure stability. The VINLS input bypass capacitor value should match or exceed the LDO output capacitor value.

#### 8.2.2.3 TS

A 10-K $\Omega$  NTC should be connected in parallel to a 10-k $\Omega$  biasing resistor connected to ground. The ground connection of both the NTC and biasing resistor must be done as close as possible to the GND pin of the device or kelvin connected to it to minimize any error in TS measurement due IR drops on the board ground lines.

If the system designer does not wish to use the TS function for charging control, a 5-k $\Omega$  resistor from TS to ground must be connected.

#### 8.2.2.4 Recommended Passive Components

表 8-2. Recommended Passive Components

|                   |                                   | MIN              | NOM | MAX | UNIT |
|-------------------|-----------------------------------|------------------|-----|-----|------|
| C <sub>PMID</sub> | Capacitance in PMID pin           | 1 <sup>(1)</sup> | 22  | 47  | μF   |
| C <sub>LDO</sub>  | LDO output capacitance            | 1                | 2.2 | 4.7 | μF   |
| C <sub>VDD</sub>  | VDD output capacitance            | 1                | 2.2 | 4.7 | μF   |
| C <sub>BAT</sub>  | BAT pin capacitance               | 1                |     | -   | μF   |
| C <sub>IN</sub>   | IN input bypass capacitance       | 1                | 4.7 | 10  | μF   |
| C <sub>INLS</sub> | VINLS input bypass capacitance    | 1                |     | -   | μF   |
| C <sub>TS</sub>   | Capacitance from TS pin to ground | 0                | 0   | 1   | nF   |

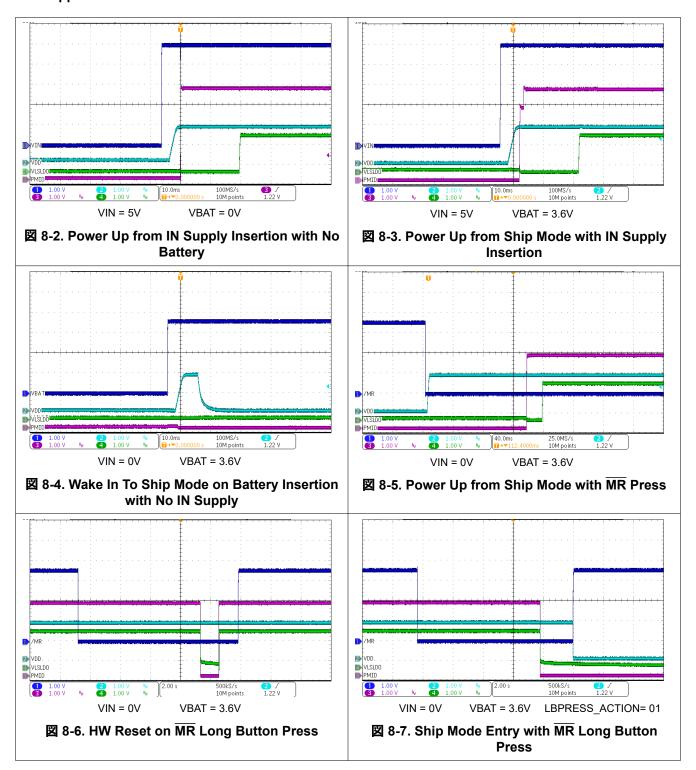
(1) For PMID regulation loop stability, for better transient performance a minimum capacitance (after derating) of 10 µF is recommended.

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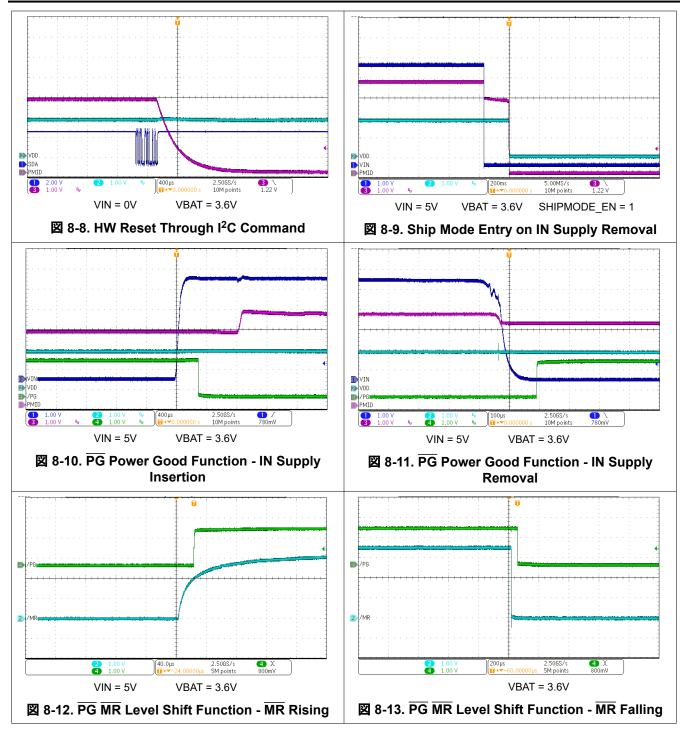
Product Folder Links: BQ21061



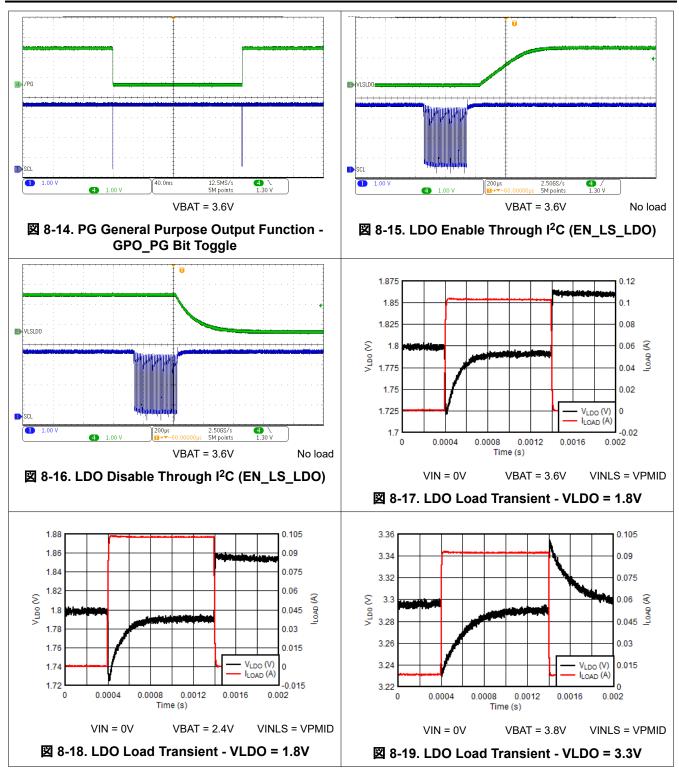
## 8.2.3 Application Curves



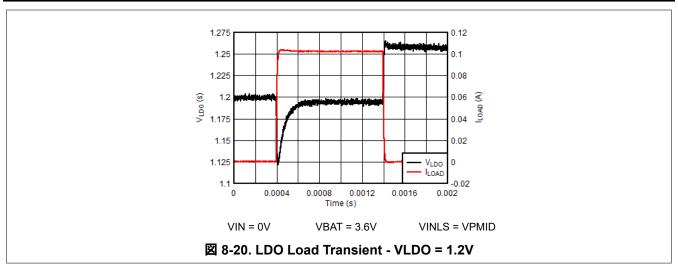












# 9 Power Supply Recommendations

The BQ21061 requires the adapter or IN supply to be between 3.4 V and 5.5 V with at least 600-mA rating. The battery voltage must be higher than 2.4 V or  $V_{BATUVLO}$  to ensure proper operation.



# 10 Layout

# 10.1 Layout Guidelines

- · Have solid ground plane that is tied to the GND bump
- Place LDO and VDD output capacitors as close as possible to the respective bumps and GND or ground plane with short copper trace connection
- Place PMID capacitor as close to the PMID bump as possible and GND or ground plane.

## 10.2 Layout Example

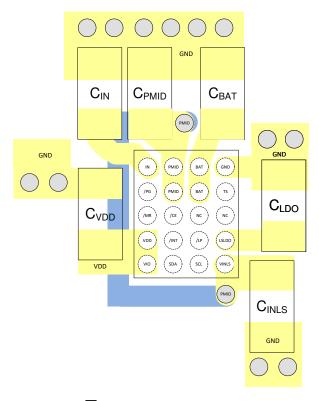


図 10-1. Layout Example



## 11 Device and Documentation Support

# 11.1 Device Support

## 11.1.1 サード・パーティ製品に関する免責事項

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#### 11.2 Documentation Support

#### 11.2.1 Related Documentation

For related documentation see the following: BQ21061EVM User's Guide and BQ21061 Setup Guide Tool

#### 11.3 ドキュメントの更新通知を受け取る方法

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#### 11.4 サポート・リソース

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# 12 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

www.ti.com 25-Jul-2023

#### PACKAGING INFORMATION

| Orderable Device | Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan     | Lead finish/<br>Ball material | MSL Peak Temp      | Op Temp (°C) | Device Marking<br>(4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|--------------|-------------------------------|--------------------|--------------|-------------------------|---------|
| BQ21061YFPR      | ACTIVE | DSBGA        | YFP                | 20   | 3000           | RoHS & Green | SNAGCU                        | Level-1-260C-UNLIM | -40 to 85    | BQ21061                 | Samples |
| BQ21061YFPT      | ACTIVE | DSBGA        | YFP                | 20   | 250            | RoHS & Green | SNAGCU                        | Level-1-260C-UNLIM | -40 to 85    | BQ21061                 | Samples |

(1) The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

(2) RoHS: TI defines "RoHS" to mean semiconductor products that are compliant with the current EU RoHS requirements for all 10 RoHS substances, including the requirement that RoHS substance do not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, "RoHS" products are suitable for use in specified lead-free processes. TI may reference these types of products as "Pb-Free".

RoHS Exempt: TI defines "RoHS Exempt" to mean products that contain lead but are compliant with EU RoHS pursuant to a specific EU RoHS exemption.

**Green:** TI defines "Green" to mean the content of Chlorine (Cl) and Bromine (Br) based flame retardants meet JS709B low halogen requirements of <=1000ppm threshold. Antimony trioxide based flame retardants must also meet the <=1000ppm threshold requirement.

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead finish/Ball material Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

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# **PACKAGE OPTION ADDENDUM**

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# **PACKAGE MATERIALS INFORMATION**

www.ti.com 7-Feb-2025

## TAPE AND REEL INFORMATION





| A0 | Dimension designed to accommodate the component width     |
|----|---|
| В0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

#### QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device      | Package<br>Type | Package<br>Drawing |    | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|-------------|-----------------|--------------------|----|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| BQ21061YFPR | DSBGA           | YFP                | 20 | 3000 | 180.0                    | 8.4                      | 1.77       | 2.17       | 0.62       | 4.0        | 8.0       | Q1               |
| BQ21061YFPT | DSBGA           | YFP                | 20 | 250  | 180.0                    | 8.4                      | 1.77       | 2.17       | 0.62       | 4.0        | 8.0       | Q1               |

**PACKAGE MATERIALS INFORMATION** 

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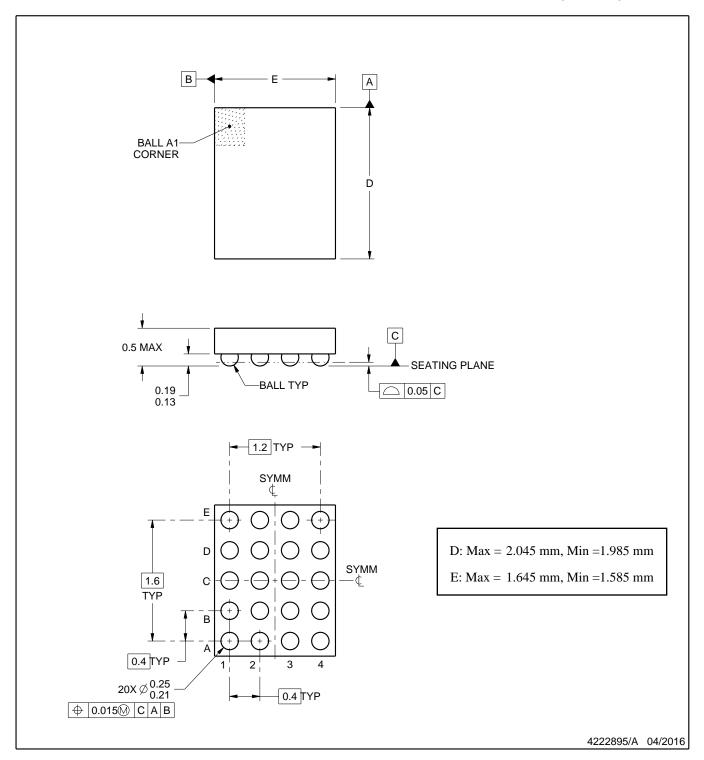


## \*All dimensions are nominal

| Device      | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|-------------|--------------|-----------------|------|------|-------------|------------|-------------|
| BQ21061YFPR | DSBGA        | YFP             | 20   | 3000 | 182.0       | 182.0      | 20.0        |
| BQ21061YFPT | DSBGA        | YFP             | 20   | 250  | 182.0       | 182.0      | 20.0        |



DIE SIZE BALL GRID ARRAY



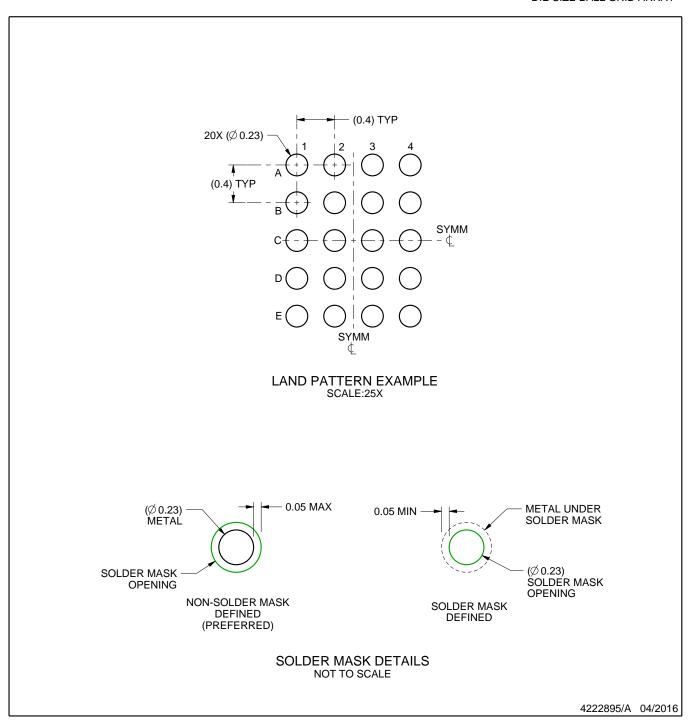
#### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.

  2. This drawing is subject to change without notice.



DIE SIZE BALL GRID ARRAY

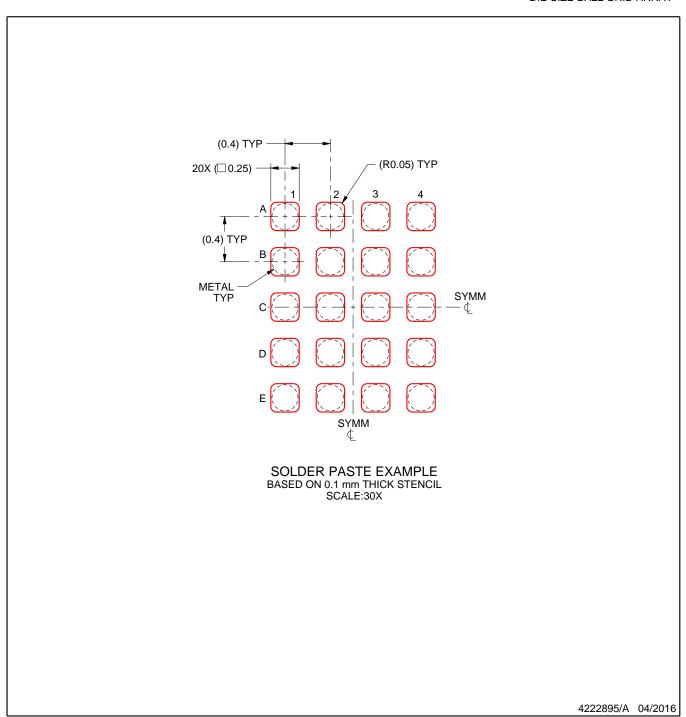


NOTES: (continued)

3. Final dimensions may vary due to manufacturing tolerance considerations and also routing constraints. For more information, see Texas Instruments literature number SNVA009 (www.ti.com/lit/snva009).



DIE SIZE BALL GRID ARRAY



NOTES: (continued)

4. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release.



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